

# CC2652P 具有集成功率放大器的 SimpleLink™ 多协议 2.4GHz 无线 MCU

## 1 特性

- 微控制器
  - 功能强大的 48MHz Arm® Cortex®-M4F 处理器
  - EEMBC CoreMark® 评分 : 148
  - 352kB 系统内可编程闪存
  - 256kB ROM, 用于协议和库函数
  - 8kB 高速缓存 SRAM ( 也可作为通用 RAM 提供 )
  - 80kB 超低泄漏 SRAM 通过奇偶校验得到保护, 从而确保高度可靠运行。
  - 2 引脚 cJTAG 和 JTAG 调试
  - 支持无线 (OTA) 升级
- 具有 4kB SRAM 的超低功耗传感器控制器
  - 采样、存储和处理传感器数据
  - 独立于系统 CPU 运行
  - 快速唤醒进入低功耗运行
- TI-RTOS、驱动程序、引导加载程序、低功耗 Bluetooth® 5.2 控制器和 IEEE 802.15.4 MAC 嵌入在 ROM 中, 优化了应用尺寸
- 符合 RoHS 标准的封装
  - 7mm × 7mm RGZ VQFN48 ( 26 个 GPIO )
- 外设
  - 数字外设可连接至任何 GPIO
  - 4 个 32 位或 8 个 16 位通用计时器
  - 12 位 ADC、200ksps、8 通道
  - 2 个具有内部基准 DAC 的比较器
    - ( 1 个连续时间比较器、1 个超低功耗比较器 )
  - 可编程电流源
  - 2x UART
  - 2 个同步串行接口 (SSI) ( SPI、MICROWIRE 和 TI )
  - I<sup>2</sup>C 和 I<sup>2</sup>S
  - 实时时钟 (RTC)
  - AES 128 位和 256 位加密加速计
  - ECC 和 RSA 公钥硬件加速器
  - SHA2 加速器 ( 包括至 SHA-512 的全套装 )
  - 真随机数发生器 (TRNG)
  - 电容式检测, 最多八个通道
  - 集成温度和电池监控器
- 外部系统
  - 片上降压直流/直流转换器

- 低功耗
  - 有源模式 RX : 6.9mA
  - 有源模式 TX 0dBm : 7.3mA
  - 有源模式 TX 5dBm : 9.6mA
  - 有源模式 TX (+10dBm) : 22mA
  - 有源模式 TX (+20dBm) : 85mA
  - 有源模式 MCU 48MHz (CoreMark) : 3.4mA (71 μA/MHz)
  - 传感器控制器, 低功耗模式, 2MHz, 运行无限循环 : 30.1 μA
  - 传感器控制器, 有源模式, 24MHz, 运行无限循环 : 808 μA
  - 待机 : 0.94μA ( RTC 运行, 80kB RAM 和 CPU 保持 )
  - 关断 : 150nA ( 发生外部事件时唤醒 )
- 无线电部分
  - 2.4GHz 射频收发器, 兼容低功耗蓝牙 5.2 与早期 LE 规范以及 IEEE 802.15.4 PHY 和 MAC
  - 3 线、2 线、1 线 PTA 共存机制
  - 出色的接收器灵敏度 :
    - 802.15.4 (2.4GHz) 标准下为 -100dBm , 蓝牙 125kbps 时 ( LE 编码 PHY ) 为 -105dBm
  - 高达 +20dBm 的输出功率, 具有温度补偿
  - 适用于符合各项全球射频规范的系统
    - EN 300 328、( 欧洲 )
    - EN 300 440 类别 2
    - FCC CFR47 第 15 部分
    - ARIB STD-T66 ( 日本 )
- 无线协议
  - Thread、Zigbee®、低功耗 Bluetooth® 5.2、IEEE 802.15.4、支持 IPv6 的智能对象 (6LoWPAN)、专有系统、SimpleLink™ TI 15.4 stack (2.4GHz) , 以及动态多协议管理器 (DMM) 驱动程序。
- 开发 [工具和软件](#)
  - SimpleLink™ LOWPOWER F2 软件开发套件 (SDK)
  - 用于简单无线电配置的 SmartRF™ Studio
  - 用于构建低功耗检测应用的 Sensor Controller Studio



本资源的原文使用英文撰写。为方便起见, TI 提供了译文; 由于翻译过程中可能使用了自动化工具, TI 不保证译文的准确性。为确认准确性, 请务必访问 [ti.com](http://ti.com) 参考最新的英文版本 (控制文档)。

## 2 应用

- 2400MHz 至 2480MHz ISM 和 SRD 系统<sup>1</sup>  
接收带宽低至 4kHz
- **楼宇自动化**
  - 楼宇安防系统 — 运动检测器、电子智能锁、门窗传感器、车库门系统、网关
  - HVAC — 恒温器、无线环境传感器、HVAC 系统控制器、网关
  - 防火安全系统 — 烟雾和热量探测器、火灾控制面板 (FACP)
  - 视频监控 — IP 网络摄像头
  - 升降机和自动扶梯 — 升降机和自动扶梯的电梯主控板
- **电网基础设施**
  - 智能仪表 — 水表、燃气表、电表和热量分配表
  - 电网通信 — 无线通信 — 远距离传感器应用

- 其他替代能源 — 能量收集
- **工业运输 — 资产跟踪**
- **工厂自动化和控制**
- **医疗**
- **电子销售终端 (EPOS) — 电子货架标签 (ESL)**
- **通信设备**
  - 有线网络 — 无线 LAN 或 Wi-Fi 接入点、边缘路由器、小型企业路由器
- **个人电子产品**
  - 便携式电子产品 — 射频智能遥控器
  - 家庭影院和娱乐 — 智能扬声器、智能显示器、机顶盒
  - 联网外设 — 消费类无线模块、指点设备、键盘
  - 游戏 — 电子玩具和机器人玩具
  - 可穿戴设备 (非医用) — 智能追踪器、智能服装

## 3 说明

SimpleLink™ CC2652P 器件是一款多协议 2.4GHz 无线微控制器 (MCU)，支持 Thread、Zigbee®、低功耗 Bluetooth® 5.2 I、IEEE 802.15.4、支持 IPv6 的智能对象 (6LoWPAN)、专有系统 (包括 2.4GHz 的 TI 15.4-Stack) 和通过动态多协议管理器 (DMM) 驱动程序实现的并发多协议。该器件经过优化，可用于楼宇安防系统、HVAC、医疗、有线网络、便携式电子产品、家庭影院和娱乐以及联网外设市场中的低功耗无线通信和高级检测。该器件的突出特性包括：

- SimpleLink™ LOWPOWER F2 软件开发套件 (SDK) 提供非常灵活的协议栈支持。
- 通过集成的 +20dBm 高功率放大器实现远距离和低功耗应用，具有较低的 85mA 发送电流消耗
- 在 +10dBm 条件下实现纽扣电池供电，发送电流消耗为 22mA
- 具有 0.94μA 的低待机电流 (完全 RAM 保持)，从而延长无线应用的电池寿命
- 支持工业温度，在 85°C 下最低待机电流为 5μA
- 通过可编程、自主式超低功耗传感器控制器 CPU 实现高级感应，具有快速唤醒功能。例如，传感器控制器能够在系统电流为 1μA 时进行 1Hz ADC 采样。
- 低 SER (软错误率) FIT (时基故障)，可延长运行寿命，不会对工业市场造成干扰，SRAM 奇偶校验功能一直开启，可防止潜在辐射事件导致的损坏
- 软件控制的专用无线电控制器 (Arm® Cortex® -M0) 提供灵活的低功耗射频收发器功能，支持多个物理层和射频标准
- 出色的无线电灵敏度和稳健性 (选择性与阻断) 性能，适用于低功耗 Bluetooth® (对于 125kbps LE 编码 PHY 为 -105dBm)。

CC2652P 器件是 SimpleLink™ MCU 平台的一部分，包括 Wi-Fi®、低功耗蓝牙、Thread、Zigbee、Sub-1GHz MCU 和主机 MCU。CC2652P 是可扩展产品系列 (闪存为 32kB 至 704kB) 的一部分，具有引脚对引脚兼容的封装选项，并共用一个简单易用的通用开发环境，其中包含单个核心软件开发套件 (SDK) 和丰富的工具集。借助一次性集成的 SimpleLink™ 平台，用户可以将产品组合中器件的任意组合添加到自己的设计中，从而在设计要求变更时实现代码的完全重复使用。如需更多信息，请访问 SimpleLink™ MCU 平台。

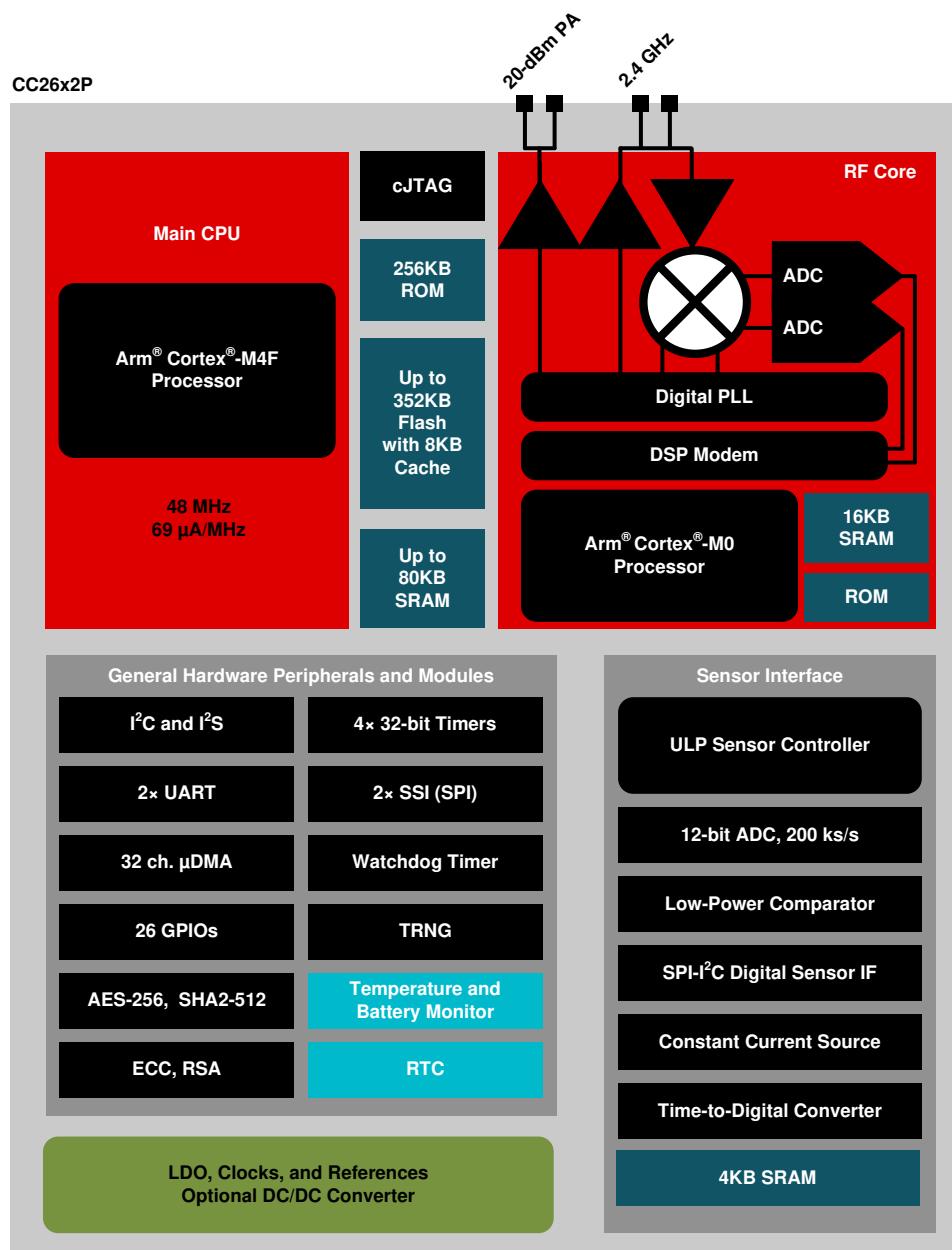
### 器件信息

器件型号 <sup>(1)</sup>	封装	封装尺寸
CC2652P1FRGZ	VQFN (48)	7.00mm × 7.00mm

(1) 如需更多信息，请参阅节 12。

<sup>1</sup> 请参阅射频内核，了解有关支持的协议标准、模块格式和数据速率的更多详细信息。

## 4 功能方框图



CC2652P 方框图

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## 5 Device Comparison

Device	RADIO SUPPORT										FLASH (kB)	RAM + Cache (kB)	GPIO	PACKAGE SIZE					
	Sub-1GHz Prop.	2.4GHz Prop.	Wireless M-Bus	mioty	Wi-SUN®	Sidewalk	Bluetooth® LE	Zigbee	Thread	Multiprotocol				4 x 4 mm VQFN (24)	4 x 4 mm VQFN (32)	5 x 5 mm VQFN (32)	5 x 5 mm VQFN (40)	7 x 7 mm VQFN (48)	8 x 8 mm VQFN (64)
CC1310	✓		✓	✓							32-128	16-20 + 8	10-30		✓	✓		✓	
CC1311R3	✓		✓	✓							352	32 + 8	22-30				✓	✓	
CC1311P3	✓		✓	✓						✓	352	32 + 8	26					✓	
CC1312R	✓		✓	✓	✓						352	80 + 8	30					✓	
CC1312R7	✓		✓	✓	✓	✓			✓		704	144 + 8	30					✓	
CC1314R10	✓		✓	✓	✓	✓				✓	1024	256 + 8	30-46					✓	✓
CC1352R	✓	✓	✓	✓	✓		✓	✓	✓	✓	352	80 + 8	28				✓		
CC1354R10	✓	✓	✓	✓	✓		✓	✓	✓	✓	1024	256 + 8	28-42				✓	✓	
CC1352P	✓	✓	✓	✓	✓		✓	✓	✓	✓	352	80 + 8	26				✓		
CC1352P7	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	704	144 + 8	26				✓		
CC1354P10	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓	1024	256 + 8	26-42				✓	✓	
CC2340R5 <sup>(1)</sup>		✓					✓	✓	✓		512	36	12-26	✓			✓		
CC2640R2F							✓				128	20 + 8	10-31		✓	✓		✓	
CC2642R							✓				352	80 + 8	31				✓		
CC2642R-Q1							✓				352	80 + 8	31				✓		
CC2651R3		✓					✓	✓			352	32 + 8	23-31				✓	✓	
CC2651P3		✓					✓	✓		✓	352	32 + 8	22-26				✓	✓	
CC2652R		✓					✓	✓	✓	✓	352	80 + 8	31				✓		
CC2652RB		✓					✓	✓	✓	✓	352	80 + 8	31				✓		
CC2652R7		✓					✓	✓	✓	✓	704	144 + 8	31				✓		
CC2652P		✓					✓	✓	✓	✓	352	80 + 8	26				✓		
CC2652P7		✓					✓	✓	✓	✓	704	144 + 8	26				✓		
CC2674R10		✓					✓	✓	✓	✓	1024	256 + 8	31-45				✓	✓	
CC2674P10		✓					✓	✓	✓	✓	1024	256 + 8	26-45				✓	✓	
CC2653P10		✓					✓	✓	✓	✓	1024	128 + 8	26				✓		

(1) Zigbee and Thread support enabled by future software update

## 6 Pin Configuration and Functions

### 6.1 Pin Diagram—RGZ Package (Top View)

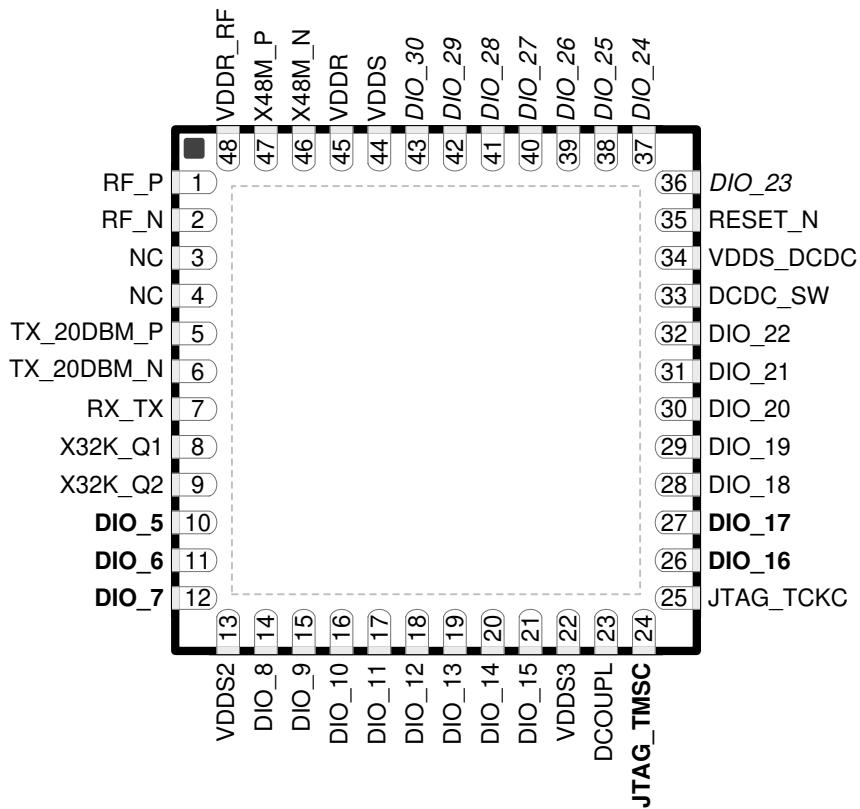


图 6-1. RGZ (7mm × 7mm) Pinout, 0.5mm Pitch (Top View)

The following I/O pins marked in [图 6-1](#) in **bold** have high-drive capabilities:

- Pin 10, **DIO\_5**
- Pin 11, **DIO\_6**
- Pin 12, **DIO\_7**
- Pin 24, **JTAG\_TMSC**
- Pin 26, **DIO\_16**
- Pin 27, **DIO\_17**

The following I/O pins marked in [图 6-1](#) in *italics* have analog capabilities:

- Pin 36, *DIO\_23*
- Pin 37, *DIO\_24*
- Pin 38, *DIO\_25*
- Pin 39, *DIO\_26*
- Pin 40, *DIO\_27*
- Pin 41, *DIO\_28*
- Pin 42, *DIO\_29*
- Pin 43, *DIO\_30*

## 6.2 Signal Descriptions—RGZ Package

**表 6-1. Signal Descriptions—RGZ Package**

PIN		I/O	TYPE	DESCRIPTION
NAME	NO.			
DCDC_SW	33	—	Power	Output from internal DC/DC converter <sup>(1)</sup>
DCOUPL	23	—	Power	For decoupling of internal 1.27V regulated digital-supply <sup>(2)</sup>
DIO_5	10	I/O	Digital	GPIO, high-drive capability
DIO_6	11	I/O	Digital	GPIO, high-drive capability
DIO_7	12	I/O	Digital	GPIO, high-drive capability
DIO_8	14	I/O	Digital	GPIO
DIO_9	15	I/O	Digital	GPIO
DIO_10	16	I/O	Digital	GPIO
DIO_11	17	I/O	Digital	GPIO
DIO_12	18	I/O	Digital	GPIO
DIO_13	19	I/O	Digital	GPIO
DIO_14	20	I/O	Digital	GPIO
DIO_15	21	I/O	Digital	GPIO
DIO_16	26	I/O	Digital	GPIO, JTAG_TDO, high-drive capability
DIO_17	27	I/O	Digital	GPIO, JTAG_TDI, high-drive capability
DIO_18	28	I/O	Digital	GPIO
DIO_19	29	I/O	Digital	GPIO
DIO_20	30	I/O	Digital	GPIO
DIO_21	31	I/O	Digital	GPIO
DIO_22	32	I/O	Digital	GPIO
DIO_23	36	I/O	Digital or Analog	GPIO, analog capability
DIO_24	37	I/O	Digital or Analog	GPIO, analog capability
DIO_25	38	I/O	Digital or Analog	GPIO, analog capability
DIO_26	39	I/O	Digital or Analog	GPIO, analog capability
DIO_27	40	I/O	Digital or Analog	GPIO, analog capability
DIO_28	41	I/O	Digital or Analog	GPIO, analog capability
DIO_29	42	I/O	Digital or Analog	GPIO, analog capability
DIO_30	43	I/O	Digital or Analog	GPIO, analog capability
EGP	—	—	GND	Ground – exposed ground pad <sup>(3)</sup>
JTAG_TMSC	24	I/O	Digital	JTAG TMSC, high-drive capability
JTAG_TCKC	25	I	Digital	JTAG TCKC
RESET_N	35	I	Digital	Reset, active low. No internal pullup resistor
RF_P	1	—	RF	Positive RF input signal to LNA during RX Positive RF output signal from PA during TX
RF_N	2	—	RF	Negative RF input signal to LNA during RX Negative RF output signal from PA during TX
RX_TX	7	—	RF	Optional bias pin for the RF LNA
TX_20DBM_P	5	—	RF	Positive high-power TX signal
TX_20DBM_N	6	—	RF	Negative high-power TX signal
VDDR	45	—	Power	Internal supply, must be powered from the internal DC/DC converter or the internal LDO <sup>(2) (4) (6)</sup>
VDDR_RF	48	—	Power	Internal supply, must be powered from the internal DC/DC converter or the internal LDO <sup>(2) (5) (6)</sup>

表 6-1. Signal Descriptions—RGZ Package (续)

PIN		I/O	TYPE	DESCRIPTION
NAME	NO.			
VDDS	44	—	Power	1.8V to 3.8V main chip supply <sup>(1)</sup>
VDDS2	13	—	Power	1.8V to 3.8V DIO supply <sup>(1)</sup>
VDDS3	22	—	Power	1.8V to 3.8V DIO supply <sup>(1)</sup>
VDDS_DCDC	34	—	Power	1.8V to 3.8V DC/DC converter supply
X48M_N	46	—	Analog	48MHz crystal oscillator pin 1
X48M_P	47	—	Analog	48MHz crystal oscillator pin 2
X32K_Q1	8	—	Analog	32kHz crystal oscillator pin 1
X32K_Q2	9	—	Analog	32kHz crystal oscillator pin 2

- (1) For more details, see technical reference manual listed in [节 10.2](#).
- (2) Do not supply external circuitry from this pin.
- (3) EGP is the only ground connection for the device. Good electrical connection to device ground on printed circuit board (PCB) is imperative for proper device operation.
- (4) If internal DC/DC converter is not used, this pin is supplied internally from the main LDO.
- (5) If internal DC/DC converter is not used, this pin must be connected to VDDR for supply from the main LDO.
- (6) Output from internal DC/DC and LDO is trimmed to 1.68V.

### 6.3 Connections for Unused Pins and Modules

表 6-2. Connections for Unused Pins

FUNCTION	SIGNAL NAME	PIN NUMBER	ACCEPTABLE PRACTICE <sup>(1)</sup>	PREFERRED PRACTICE <sup>(1)</sup>
GPIO	DIO_n	10 - 12 14 - 21 26 - 32 36 - 43	NC or GND	NC
32.768kHz crystal	X32K_Q1	8	NC or GND	NC
	X32K_Q2	9		
No Connects	NC	3 - 4	NC	NC
DC/DC converter <sup>(2)</sup>	DCDC_SW	33	NC	NC
	VDDS_DCDC	34	VDDS	VDDS

- (1) NC = No connect
- (2) When the DC/DC converter is not used, the inductor between DCDC\_SW and VDDR can be removed. VDDR and VDDR\_RF must still be connected and the 22 $\mu$ F DCDC capacitor must be kept on the VDDR net.

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1) (2)</sup>

			MIN	MAX	UNIT
VDDS <sup>(3)</sup>	Supply voltage		- 0.3	4.1	V
	Voltage on any digital pin <sup>(4) (5)</sup>		- 0.3	VDDS + 0.3, max 4.1	V
	Voltage on crystal oscillator pins, X32K_Q1, X32K_Q2, X48M_N and X48M_P		- 0.3	VDDR + 0.3, max 2.25	V
V <sub>in</sub>	Voltage on ADC input	Voltage scaling enabled	- 0.3	VDDS	V
		Voltage scaling disabled, internal reference	- 0.3	1.49	
		Voltage scaling disabled, VDDS as reference	- 0.3	VDDS / 2.9	
	Input level, RF pins			5	dBm
T <sub>stg</sub>	Storage temperature		- 40	150	°C

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime
- (2) All voltage values are with respect to ground, unless otherwise noted.
- (3) VDDS\_DCDC, VDDS2 and VDDS3 must be at the same potential as VDDS.
- (4) Including analog capable DIOs.
- (5) Injection current is not supported on any GPIO pin

### 7.2 ESD Ratings

			VALUE	UNIT
V <sub>ESD</sub>	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS001 <sup>(1)</sup>	All pins	±2000
		Charged device model (CDM), per JESD22-C101 <sup>(2)</sup>	All pins	±500

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

### 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
Operating junction temperature		- 40	105	°C
Operating supply voltage (VDDS)		1.8	3.8	V
Rising supply voltage slew rate		0	100	mV/μs
Falling supply voltage slew rate <sup>(1)</sup>		0	20	mV/μs

- (1) For small coin-cell batteries, with high worst-case end-of-life equivalent source resistance, a 22μF VDDS input capacitor must be used to ensure compliance with this slew rate.

### 7.4 Power Supply and Modules

over operating free-air temperature range (unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNIT
VDDS Power-on-Reset (POR) threshold			1.1 - 1.55		V
VDDS Brown-out Detector (BOD) <sup>(1)</sup>	Rising threshold		1.77		V
VDDS Brown-out Detector (BOD), before initial boot <sup>(2)</sup>	Rising threshold		1.70		V
VDDS Brown-out Detector (BOD) <sup>(1)</sup>	Falling threshold		1.75		V

- (1) For boost mode (VDDR = 1.95V), TI drivers software initialization will trim VDDS BOD limits to maximum (approximately 2.0V)
- (2) Brown-out Detector is trimmed at initial boot, value is kept until device is reset by a POR reset or the RESET\_N pin

## 7.5 Power Consumption—Power Modes

When measured on the CC1352PEM-XD7793-XD24-PA24 reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{DD} = 3.0\text{V}$  with DC/DC enabled unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>Core Current Consumption</b>					
$I_{core}$	Reset. RESET_N pin asserted or VDD below power-on-reset threshold	150			nA
	Shutdown. No clocks running, no retention	150			
	Standby without cache retention	0.94			$\mu\text{A}$
	RTC running, CPU, 80kB RAM and (partial) register retention. RCOSC_LF	1.09			
	Standby with cache retention	3.2			$\mu\text{A}$
	RTC running, CPU, 80kB RAM and (partial) register retention. RCOSC_LF	3.3			
	Idle	675			$\mu\text{A}$
	Active	3.39			
	MCU running CoreMark at 48MHz RCOSC_HF				$\text{mA}$
<b>Peripheral Current Consumption<sup>(1), (2)</sup></b>					
$I_{peri}$	Peripheral power domain	97.7			$\mu\text{A}$
	Serial power domain	7.2			
	RF Core	210.9			
	$\mu\text{DMA}$	63.9			
	Timers	81.0			
	I <sup>2</sup> C	10.1			
	I <sup>2</sup> S	26.3			
	SSI	82.9			
	UART	167.5			
	CRYPTO (AES)	25.6			
	PKA	84.7			
	TRNG	35.6			
<b>Sensor Controller Engine Consumption</b>					
$I_{SCE}$	Active mode	24MHz, infinite loop	808.5		$\mu\text{A}$
	Low-power mode	2MHz, infinite loop	30.1		

## 7.6 Power Consumption—Radio Modes

When measured on the CC1352PEM-XD7793-XD24-PA24 reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$  with DC/DC enabled unless otherwise noted.

High-power PA connected to  $V_{\text{DDS}}$  unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Radio receive current	2440MHz		6.9		mA
Radio transmit current 2.4 GHz PA (BLE)	0dBm output power setting 2440MHz		7.0		mA
	+5dBm output power setting 2440MHz		9.2		mA
Radio transmit current High-power PA	+20dBm output power setting 2440MHz. $V_{\text{DDS}} = 3.3\text{V}$		85		mA
Radio transmit current High-power PA, 10dBm configuration <sup>(1)</sup>	+10dBm output power setting 2440MHz $V_{\text{DDR}} = 1.67\text{V}$		22		mA

(1) Measured on evaluation board (See [Optimizing the CC1352P and CC2652P for Coin Cell Operation at 10dBm Output Power](#).)

## 7.7 Nonvolatile (Flash) Memory Characteristics

Over operating free-air temperature range and  $V_{\text{DDS}} = 3.0\text{V}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Flash sector size			8		KB
Supported flash erase cycles before failure, full bank <sup>(1) (5)</sup>		30			k Cycles
Supported flash erase cycles before failure, single sector <sup>(2)</sup>		60			k Cycles
Maximum number of write operations per row before sector erase <sup>(3)</sup>			83		Write Operations
Flash retention	85°C	11.4			Years at 85°C
Flash sector erase current	Average delta current	10.7			mA
Flash sector erase time <sup>(4)</sup>	Zero cycles	10			ms
Flash write current	Average delta current, 4 bytes at a time	6.2			mA
Flash write time <sup>(4)</sup>	4 bytes at a time	21.6			μs

(1) A full bank erase is counted as a single erase cycle on each sector

(2) Up to four customer-designated sectors can be individually erased an additional 30k times beyond the baseline bank limitation of 30k cycles

(3) Each wordline is 2048 bits (or 256 bytes) wide. This limitation corresponds to sequential memory writes of 4 (3.1) bytes minimum per write over a whole wordline. If additional writes to the same wordline are required, a sector erase is required once the maximum number of write operations per row is reached.

(4) This number is dependent on Flash aging and increases over time and erase cycles

(5) Aborting flash during erase or program modes is not a safe operation.

## 7.8 Thermal Resistance Characteristics

THERMAL METRIC <sup>(1)</sup>		PACKAGE	UNIT
		RGZ (VQFN)	
		48 PINS	
$R_{\text{JA}}$	Junction-to-ambient thermal resistance	23.4	°C/W <sup>(2)</sup>
$R_{\text{JC(top)}}$	Junction-to-case (top) thermal resistance	13.3	°C/W <sup>(2)</sup>
$R_{\text{JB}}$	Junction-to-board thermal resistance	8.0	°C/W <sup>(2)</sup>
$\psi_{\text{JT}}$	Junction-to-top characterization parameter	0.1	°C/W <sup>(2)</sup>
$\psi_{\text{JB}}$	Junction-to-board characterization parameter	7.9	°C/W <sup>(2)</sup>
$R_{\text{JC(bot)}}$	Junction-to-case (bottom) thermal resistance	1.7	°C/W <sup>(2)</sup>

(1) For more information about traditional and new thermal metrics, see [Semiconductor and IC Package Thermal Metrics](#).

(2) °C/W = degrees Celsius per watt.

## 7.9 RF Frequency Bands

Over operating free-air temperature range (unless otherwise noted).

PARAMETER	MIN	TYP	MAX	UNIT
Frequency bands	2360		2500	MHz

## 7.10 Bluetooth Low Energy—Receive (RX)

Measured on the CC1352PEM-XD7793-XD24-PA24 reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ ,  $f_{\text{RF}} = 2440\text{MHz}$  with DC/DC enabled and the high-power PA connected to  $V_{\text{DDS}}$  unless otherwise noted.

All measurements are performed at the antenna input with a combined RX and TX path, except for the high-power PA, which is measured at a dedicated antenna connection. All measurements are performed and conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>125kbps (LE Coded)</b>					
Receiver sensitivity	Differential mode, BER = $10^{-3}$		- 105		dBm
Receiver saturation	Differential mode, BER = $10^{-3}$		> 5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency		> (- 300 / 300)		kHz
Data rate error tolerance	Difference between the incoming data rate and the internally generated data rate (37-byte packets)		> (- 320 / 240)		ppm
Data rate error tolerance	Difference between the incoming data rate and the internally generated data rate (255-byte packets)		> (- 125 / 125)		ppm
Co-channel rejection <sup>(1)</sup>	Wanted signal at - 79dBm, modulated interferer in channel, BER = $10^{-3}$		- 1.5		dB
Selectivity, $\pm 1\text{MHz}$ <sup>(1)</sup>	Wanted signal at - 79dBm, modulated interferer at $\pm 1\text{MHz}$ , BER = $10^{-3}$		8 / 4.5 <sup>(2)</sup>		dB
Selectivity, $\pm 2\text{MHz}$ <sup>(1)</sup>	Wanted signal at - 79dBm, modulated interferer at $\pm 2\text{MHz}$ , BER = $10^{-3}$		44 / 39 <sup>(2)</sup>		dB
Selectivity, $\pm 3\text{MHz}$ <sup>(1)</sup>	Wanted signal at - 79dBm, modulated interferer at $\pm 3\text{MHz}$ , BER = $10^{-3}$		46 / 44 <sup>(2)</sup>		dB
Selectivity, $\pm 4\text{MHz}$ <sup>(1)</sup>	Wanted signal at - 79dBm, modulated interferer at $\pm 4\text{MHz}$ , BER = $10^{-3}$		44 / 46 <sup>(2)</sup>		dB
Selectivity, $\pm 6\text{MHz}$ <sup>(1)</sup>	Wanted signal at - 79dBm, modulated interferer at $\geq \pm 6\text{MHz}$ , BER = $10^{-3}$		48 / 44 <sup>(2)</sup>		dB
Selectivity, $\pm 7\text{MHz}$	Wanted signal at - 79dBm, modulated interferer at $\geq \pm 7\text{MHz}$ , BER = $10^{-3}$		51 / 45 <sup>(2)</sup>		dB
Selectivity, Image frequency <sup>(1)</sup>	Wanted signal at - 79dBm, modulated interferer at image frequency, BER = $10^{-3}$				dB
Selectivity, Image frequency $\pm 1\text{MHz}$ <sup>(1)</sup>	Note that Image frequency + 1MHz is the co-channel - 1MHz. Wanted signal at - 79dBm, modulated interferer at $\pm 1\text{MHz}$ from image frequency, BER = $10^{-3}$		4.5 / 44 <sup>(2)</sup>		dB
<b>500kbps (LE Coded)</b>					
Receiver sensitivity	Differential mode, BER = $10^{-3}$		- 100		dBm
Receiver saturation	Differential mode, BER = $10^{-3}$		> 5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency		> (- 300 / 300)		kHz
Data rate error tolerance	Difference between the incoming data rate and the internally generated data rate (37-byte packets)		> (- 450 / 450)		ppm
Data rate error tolerance	Difference between the incoming data rate and the internally generated data rate (255-byte packets)		> (- 175 / 175)		ppm
Co-channel rejection <sup>(1)</sup>	Wanted signal at - 72dBm, modulated interferer in channel, BER = $10^{-3}$		- 3.5		dB
Selectivity, $\pm 1\text{MHz}$ <sup>(1)</sup>	Wanted signal at - 72dBm, modulated interferer at $\pm 1\text{MHz}$ , BER = $10^{-3}$		8 / 4 <sup>(2)</sup>		dB

## 7.10 Bluetooth Low Energy—Receive (RX) (续)

Measured on the CC1352PEM-XD7793-XD24-PA24 reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ ,  $f_{\text{RF}} = 2440\text{MHz}$  with DC/DC enabled and the high-power PA connected to  $V_{\text{DDS}}$  unless otherwise noted.

All measurements are performed at the antenna input with a combined RX and TX path, except for the high-power PA, which is measured at a dedicated antenna connection. All measurements are performed and conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Selectivity, $\pm 2\text{MHz}$ <sup>(1)</sup>	Wanted signal at $-72\text{dBm}$ , modulated interferer at $\pm 2\text{MHz}$ , $\text{BER} = 10^{-3}$		44 / 37 <sup>(2)</sup>		dB
Selectivity, $\pm 3\text{MHz}$ <sup>(1)</sup>	Wanted signal at $-72\text{dBm}$ , modulated interferer at $\pm 3\text{MHz}$ , $\text{BER} = 10^{-3}$		46 / 46 <sup>(2)</sup>		dB
Selectivity, $\pm 4\text{MHz}$ <sup>(1)</sup>	Wanted signal at $-72\text{dBm}$ , modulated interferer at $\pm 4\text{MHz}$ , $\text{BER} = 10^{-3}$		45 / 47 <sup>(2)</sup>		dB
Selectivity, $\pm 6\text{MHz}$ <sup>(1)</sup>	Wanted signal at $-72\text{dBm}$ , modulated interferer at $\geq \pm 6\text{MHz}$ , $\text{BER} = 10^{-3}$		46 / 45 <sup>(2)</sup>		dB
Selectivity, $\pm 7\text{MHz}$	Wanted signal at $-72\text{dBm}$ , modulated interferer at $\geq \pm 7\text{MHz}$ , $\text{BER} = 10^{-3}$		49 / 45 <sup>(2)</sup>		dB
Selectivity, Image frequency <sup>(1)</sup>	Wanted signal at $-72\text{dBm}$ , modulated interferer at image frequency, $\text{BER} = 10^{-3}$				dB
Selectivity, Image frequency $\pm 1\text{MHz}$ <sup>(1)</sup>	Note that Image frequency + 1MHz is the co-channel - 1MHz. Wanted signal at $-72\text{dBm}$ , modulated interferer at $\pm 1\text{MHz}$ from image frequency, $\text{BER} = 10^{-3}$		4 / 46 <sup>(2)</sup>		dB
<b>1Mbps (LE 1M)</b>					
Receiver sensitivity	Differential mode, $\text{BER} = 10^{-3}$		- 97		dBm
Receiver saturation	Differential mode, $\text{BER} = 10^{-3}$		> 5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency		> (- 350 / 350)		kHz
Data rate error tolerance	Difference between the incoming data rate and the internally generated data rate (37-byte packets)		> (- 750 / 750)		ppm
Co-channel rejection <sup>(1)</sup>	Wanted signal at $-67\text{dBm}$ , modulated interferer in channel, $\text{BER} = 10^{-3}$		- 6		dB
Selectivity, $\pm 1\text{MHz}$ <sup>(1)</sup>	Wanted signal at $-67\text{dBm}$ , modulated interferer at $\pm 1\text{MHz}$ , $\text{BER} = 10^{-3}$		7 / 4 <sup>(2)</sup>		dB
Selectivity, $\pm 2\text{MHz}$ <sup>(1)</sup>	Wanted signal at $-67\text{dBm}$ , modulated interferer at $\pm 2\text{MHz}$ , $\text{BER} = 10^{-3}$		40 / 33 <sup>(2)</sup>		dB
Selectivity, $\pm 3\text{MHz}$ <sup>(1)</sup>	Wanted signal at $-67\text{dBm}$ , modulated interferer at $\pm 3\text{MHz}$ , $\text{BER} = 10^{-3}$		36 / 41 <sup>(2)</sup>		dB
Selectivity, $\pm 4\text{MHz}$ <sup>(1)</sup>	Wanted signal at $-67\text{dBm}$ , modulated interferer at $\pm 4\text{MHz}$ , $\text{BER} = 10^{-3}$		36 / 45 <sup>(2)</sup>		dB
Selectivity, $\pm 5\text{MHz}$ or more <sup>(1)</sup>	Wanted signal at $-67\text{dBm}$ , modulated interferer at $\geq \pm 5\text{MHz}$ , $\text{BER} = 10^{-3}$		40		dB
Selectivity, image frequency <sup>(1)</sup>	Wanted signal at $-67\text{dBm}$ , modulated interferer at image frequency, $\text{BER} = 10^{-3}$		33		dB
Selectivity, image frequency $\pm 1\text{MHz}$ <sup>(1)</sup>	Note that Image frequency + 1MHz is the co-channel - 1MHz. Wanted signal at $-67\text{dBm}$ , modulated interferer at $\pm 1\text{MHz}$ from image frequency, $\text{BER} = 10^{-3}$		4 / 41 <sup>(2)</sup>		dB
Out-of-band blocking <sup>(3)</sup>	30MHz to 2000MHz		- 10		dBm
Out-of-band blocking	2003MHz to 2399MHz		- 18		dBm
Out-of-band blocking	2484MHz to 2997MHz		- 12		dBm
Out-of-band blocking	3000MHz to 12.75GHz		- 2		dBm
Intermodulation	Wanted signal at 2402MHz, - 64 dBm. Two interferers at 2405MHz and 2408MHz, respectively, at the given power level		- 42		dBm
Spurious emissions, 30MHz to 1000MHz <sup>(4)</sup>	Measurement in a $50\Omega$ single-ended load		< - 59		dBm
Spurious emissions, 1 to 12.75GHz <sup>(4)</sup>	Measurement in a $50\Omega$ single-ended load		< - 47		dBm
RSSI dynamic range			70		dB

## 7.10 Bluetooth Low Energy—Receive (RX) (续)

Measured on the CC1352PEM-XD7793-XD24-PA24 reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ ,  $f_{\text{RF}} = 2440\text{MHz}$  with DC/DC enabled and the high-power PA connected to  $V_{\text{DDS}}$  unless otherwise noted.

All measurements are performed at the antenna input with a combined RX and TX path, except for the high-power PA, which is measured at a dedicated antenna connection. All measurements are performed and conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
RSSI accuracy			$\pm 4$		dB
<b>2Mbps (LE 2M)</b>					
Receiver sensitivity	Differential mode. Measured at SMA connector, BER = $10^{-3}$		- 92		dBm
Receiver saturation	Differential mode. Measured at SMA connector, BER = $10^{-3}$		> 5		dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency		> (- 500 / 500)		kHz
Data rate error tolerance	Difference between the incoming data rate and the internally generated data rate (37-byte packets)		> (- 700 / 750)		ppm
Co-channel rejection <sup>(1)</sup>	Wanted signal at - 67dBm, modulated interferer in channel, BER = $10^{-3}$		- 7		dB
Selectivity, $\pm 2\text{MHz}$ <sup>(1)</sup>	Wanted signal at - 67dBm, modulated interferer at $\pm 2\text{MHz}$ , Image frequency is at - 2MHz, BER = $10^{-3}$		8 / 4 <sup>(2)</sup>		dB
Selectivity, $\pm 4\text{MHz}$ <sup>(1)</sup>	Wanted signal at - 67dBm, modulated interferer at $\pm 4\text{MHz}$ , BER = $10^{-3}$		36 / 36 <sup>(2)</sup>		dB
Selectivity, $\pm 6\text{MHz}$ <sup>(1)</sup>	Wanted signal at - 67dBm, modulated interferer at $\pm 6\text{MHz}$ , BER = $10^{-3}$		37 / 36 <sup>(2)</sup>		dB
Selectivity, image frequency <sup>(1)</sup>	Wanted signal at - 67dBm, modulated interferer at image frequency, BER = $10^{-3}$		4		dB
Selectivity, image frequency $\pm 2\text{MHz}$ <sup>(1)</sup>	Note that Image frequency + 2MHz is the Co-channel. Wanted signal at - 67dBm, modulated interferer at $\pm 2\text{MHz}$ from image frequency, BER = $10^{-3}$		- 7 / 36 <sup>(2)</sup>		dB
Out-of-band blocking <sup>(3)</sup>	30MHz to 2000MHz		- 16		dBm
Out-of-band blocking	2003MHz to 2399MHz		- 21		dBm
Out-of-band blocking	2484MHz to 2997MHz		- 15		dBm
Out-of-band blocking	3000MHz to 12.75 GHz		- 12		dBm
Intermodulation	Wanted signal at 2402MHz, - 64 dBm. Two interferers at 2408 and 2414MHz respectively, at the given power level		- 38		dBm

(1) Numbers given as I/C dB

(2) X / Y, where X is +N MHz and Y is - N MHz

(3) Excluding one exception at  $F_{\text{wanted}} / 2$ , per Bluetooth Specification

(4) Suitable for systems targeting compliance with worldwide radio-frequency regulations ETSI EN 300 328 and EN 300 440 Class 2 (Europe), FCC CFR47 Part 15 (US), and ARIB STD-T66 (Japan)

## 7.11 Bluetooth Low Energy—Transmit (TX)

Measured on the CC1352PEM-XD7793-XD24-PA24 reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ ,  $f_{\text{RF}} = 2440\text{MHz}$  with DC/DC enabled and high power PA connected to  $V_{\text{DDS}}$  unless otherwise noted.

All measurements are performed at the antenna input with a combined RX and TX path, except for high power PA which is measured at a dedicated antenna connection. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>General Parameters</b>					
Max output power, high power PA	Differential mode, delivered to a single-ended $50\ \Omega$ load through a balun	19.5			dBm
Output power programmable range high power PA	Differential mode, delivered to a single-ended $50\ \Omega$ load through a balun	6			dB
Max output power, high power PA, 10dBm configuration <sup>(4)</sup>	Differential mode, delivered to a single-ended $50\ \Omega$ load through a balun	10.5			dBm
Output power programmable range high power PA, 10dBm configuration <sup>(4)</sup>	Differential mode, delivered to a single-ended $50\ \Omega$ load through a balun	5			dB
Max output power, regular PA	Differential mode, delivered to a single-ended $50\ \Omega$ load through a balun	5			dBm
Output power programmable range, regular PA	Differential mode, delivered to a single-ended $50\ \Omega$ load through a balun	26			dB
<b>Spurious emissions and harmonics</b>					
Spurious emissions, high-power PA <sup>(1) (2)</sup>	f < 1GHz, outside restricted bands	+20dBm setting	< -36		dBm
	f < 1GHz, restricted bands FCC		< -55		dBm
	f > 1GHz, including harmonics		-37		dBm
Harmonics, high-power PA <sup>(1) (3)</sup>	Second harmonic		-35		dBm
	Third harmonic		-42		dBm
	f < 1GHz, outside restricted bands		< -36		dBm
Spurious emissions, high-power PA, 10dBm configuration <sup>(1) (2) (4)</sup>	f < 1GHz, restricted bands ETSI		< -54		dBm
	f < 1GHz, restricted bands FCC		< -55		dBm
	f > 1GHz, including harmonics		-41		dBm
	f < 1GHz, outside restricted bands		< -42		dBm
Harmonics, high-power PA, 10dBm configuration <sup>(1) (4)</sup>	Second harmonic		< -42		dBm
	Third harmonic		< -42		dBm
	f < 1GHz, outside restricted bands		< -36		dBm
Spurious emissions, regular PA <sup>(1)</sup>	f < 1GHz, restricted bands ETSI		< -54		dBm
	f < 1GHz, restricted bands FCC		< -55		dBm
	f > 1GHz, including harmonics		< -42		dBm
	Second harmonic		< -42		dBm
Harmonics, regular PA <sup>(1)</sup>	Third harmonic		< -42		dBm

- (1) Suitable for systems targeting compliance with worldwide radio-frequency regulations ETSI EN 300 328 and EN 300 440 Class 2 (Europe), FCC CFR47 Part 15 (US), and ARIB STD-T66 (Japan).
- (2) To ensure margins for passing FCC band edge requirements at 2483.5MHz, a lower than maximum output-power setting or less than 100% duty cycle may be used when operating at the upper BLE channel(s).
- (3) To ensure margins for passing FCC requirements for harmonic emission, duty cycling may be required. The CC1352P-2 LaunchPad reference design should also be reviewed as the filter provides higher attenuation of harmonics compared to the CC1352PEM-XD7793-XD24-PA24 reference design.
- (4) Measured on evaluation board as described in [Optimizing the CC1352P and CC2652P for Coin Cell Operation at 10dBm Output Power](#).

## 7.12 Zigbee and Thread—IEEE 802.15.4-2006 2.4GHz (OQPSK DSSS1:8, 250kbps): RX

Measured on the CC1352PEM-XD7793-XD24-PA24 reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ ,  $f_{\text{RF}} = 2440\text{MHz}$  with DC/DC enabled and high power PA connected to  $V_{\text{DDS}}$  unless otherwise noted.

All measurements are performed at the antenna input with a combined RX and TX path, except for high power PA which is measured at a dedicated antenna connection. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>General Parameters</b>					
Receiver sensitivity	PER = 1%	- 100			dBm
Receiver saturation	PER = 1%	> 5			dBm
Adjacent channel rejection	Wanted signal at - 82dBm, modulated interferer at $\pm 5\text{MHz}$ , PER = 1%	36			dB
Alternate channel rejection	Wanted signal at - 82dBm, modulated interferer at $\pm 10\text{MHz}$ , PER = 1%	57			dB
Channel rejection, $\pm 15\text{MHz}$ or more	Wanted signal at - 82dBm, undesired signal is IEEE 802.15.4 modulated channel, stepped through all channels 2405MHz to 2480MHz, PER = 1%	59			dB
Blocking and desensitization, 5MHz from upper band edge	Wanted signal at - 97dBm (3dB above the sensitivity level), CW jammer, PER = 1%	57			dB
Blocking and desensitization, 10MHz from upper band edge	Wanted signal at - 97dBm (3dB above the sensitivity level), CW jammer, PER = 1%	63			dB
Blocking and desensitization, 20MHz from upper band edge	Wanted signal at - 97dBm (3dB above the sensitivity level), CW jammer, PER = 1%	63			dB
Blocking and desensitization, 50MHz from upper band edge	Wanted signal at - 97dBm (3dB above the sensitivity level), CW jammer, PER = 1%	66			dB
Blocking and desensitization, - 5MHz from lower band edge	Wanted signal at - 97dBm (3dB above the sensitivity level), CW jammer, PER = 1%	60			dB
Blocking and desensitization, - 10MHz from lower band edge	Wanted signal at - 97dBm (3dB above the sensitivity level), CW jammer, PER = 1%	60			dB
Blocking and desensitization, - 20MHz from lower band edge	Wanted signal at - 97dBm (3dB above the sensitivity level), CW jammer, PER = 1%	63			dB
Blocking and desensitization, - 50MHz from lower band edge	Wanted signal at - 97dBm (3dB above the sensitivity level), CW jammer, PER = 1%	65			dB
Spurious emissions, 30MHz to 1000MHz <sup>(1)</sup>	Measurement in a $50\Omega$ single-ended load	- 66			dBm
Spurious emissions, 1GHz to 12.75GHz <sup>(1)</sup>	Measurement in a $50\Omega$ single-ended load	- 53			dBm
Frequency error tolerance	Difference between the incoming carrier frequency and the internally generated carrier frequency	> 350			ppm
Symbol rate error tolerance	Difference between incoming symbol rate and the internally generated symbol rate	> 1000			ppm
RSSI dynamic range		95			dB
RSSI accuracy		$\pm 4$			dB

(1) Suitable for systems targeting compliance with worldwide radio-frequency regulations ETSI EN 300 328 and EN 300 440 Class 2 (Europe), FCC CFR47 Part 15 (US), and ARIB STD-T66 (Japan)

## 7.13 Zigbee and Thread—IEEE 802.15.4-2006 2.4GHz (OQPSK DSSS1:8, 250kbps): TX

Measured on the CC1352PEM-XD7793-XD24-PA24 reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ ,  $f_{\text{RF}} = 2440\text{MHz}$  with DC/DC enabled and high power PA connected to  $V_{\text{DDS}}$  unless otherwise noted.

All measurements are performed at the antenna input with a combined RX and TX path, except for high power PA which is measured at a dedicated antenna connection. All measurements are performed conducted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>General Parameters</b>					
Max output power, high power PA	Differential mode, delivered to a single-ended $50\ \Omega$ load through a balun	19.5			dBm
Output power programmable range, high power PA	Differential mode, delivered to a single-ended $50\ \Omega$ load through a balun	6			dB
Max output power, high power PA, 10dBm configuration <sup>(5)</sup>	Differential mode, delivered to a single-ended $50\ \Omega$ load through a balun	10.5			dBm
Output power programmable range, high power PA, 10dBm configuration <sup>(5)</sup>	Differential mode, delivered to a single-ended $50\ \Omega$ load through a balun	5			dB
Max output power, regular PA	Differential mode, delivered to a single-ended $50\ \Omega$ load through a balun	5			dBm
Output power programmable range, regular PA	Differential mode, delivered to a single-ended $50\ \Omega$ load through a balun	26			dB
<b>Spurious emissions and harmonics</b>					
Spurious emissions, high-power PA <sup>(1) (3)</sup>	f < 1GHz, outside restricted bands	+20dBm setting	< -39		dBm
	f < 1GHz, restricted bands FCC		< -49		dBm
	f > 1GHz, including harmonics		-40		dBm
Harmonics, high-power PA <sup>(1) (4)</sup>	Second harmonic		-35		dBm
	Third harmonic		-42		dBm
Spurious emissions, high-power PA, 10dBm configuration <sup>(1) (3) (5)</sup>	f < 1GHz, outside restricted bands		< -36		dBm
	f < 1GHz, restricted bands ETSI		< -47		dBm
	f < 1GHz, restricted bands FCC		< -55		dBm
	f > 1GHz, including harmonics		-42		dBm
Harmonics, high-power PA, 10dBm configuration <sup>(1) (6)</sup>	Second harmonic		< -42		dBm
	Third harmonic		< -42		dBm
Spurious emissions, regular PA <sup>(1) (2)</sup>	f < 1GHz, outside restricted bands	+5dBm setting	< -36		dBm
	f < 1GHz, restricted bands ETSI		< -47		dBm
	f < 1GHz, restricted bands FCC		< -55		dBm
	f > 1GHz, including harmonics		-42		dBm
Harmonics, regular PA <sup>(1)</sup>	Second harmonic		< -42		dBm
	Third harmonic		< -42		dBm
<b>IEEE 802.15.4-2006 2.4GHz (OQPSK DSSS1:8, 250kbps)</b>					
Error vector magnitude, high power PA	+20dBm setting		2%		
Error vector magnitude, high power PA, 10dBm configuration <sup>(5)</sup>	+10dBm setting		2%		
Error vector magnitude, Regular PA	+5dBm setting		2%		

(1) Suitable for systems targeting compliance with worldwide radio-frequency regulations ETSI EN 300 328 and EN 300 440 Class 2 (Europe), FCC CFR47 Part 15 (US), and ARIB STD-T66 (Japan).

- (2) To ensure margins for passing FCC band edge requirements at 2483.5MHz, a lower than maximum output-power setting or less than 100% duty cycle may be used when operating at 2480MHz.
- (3) To ensure margins for passing FCC band edge requirements at 2483.5MHz, a lower than maximum output-power setting or less than 100% duty cycle may be used when operating at the upper 802.15.4 channel(s).
- (4) To ensure margins for passing FCC requirements for harmonic emission, duty cycling may be required. The CC1352P-2 LaunchPad reference design should also be reviewed as the filter provides higher attenuation of harmonics compared to the CC1352PEM-XD7793-XD24-PA24 reference design.
- (5) Measured on evaluation board as described in [Optimizing the CC1352P and CC2652P for Coin Cell Operation at 10dBm Output Power](#).

## 7.14 Timing and Switching Characteristics

### 7.14.1 Reset Timing

PARAMETER	MIN	TYP	MAX	UNIT
RESET_N low duration	1			μs

### 7.14.2 Wakeup Timing

Measured over operating free-air temperature with  $V_{DDS} = 3.0V$  (unless otherwise noted). The times listed here do not include software overhead.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
MCU, Reset to Active Timing		850 - 4000			μs
MCU, Shutdown to Active Timing <sup>(1)</sup>		850 - 4000			μs
MCU, Standby to Active		160			μs
MCU, Active to Standby		36			μs
MCU, Idle to Active		14			μs

- (1) The wakeup time is dependent on remaining charge on VDDR capacitor when starting the device, and thus how long the device has been in Reset or Shutdown before starting up again. The wake up time increases with a higher capacitor value.

### 7.14.3 Clock Specifications

#### 7.14.3.1 48MHz Crystal Oscillator (XOSC\_HF)

Measured on a Texas Instruments reference design with  $T_c = 25^\circ C$ ,  $V_{DDS} = 3.0V$ , unless otherwise noted.<sup>(1)</sup>

	PARAMETER	MIN	TYP	MAX	UNIT
	Crystal frequency		48		MHz
ESR	Equivalent series resistance 6 pF < $C_L \leq 9$ pF		20	60	Ω
ESR	Equivalent series resistance 5 pF < $C_L \leq 6$ pF		80		Ω
$L_M$	Motional inductance, relates to the load capacitance that is used for the crystal ( $C_L$ in Farads) <sup>(5)</sup>	$< 3 \times 10^{-25} / C_L^2$			H
$C_L$	Crystal load capacitance <sup>(4)</sup>	5	7 <sup>(3)</sup>	9	pF
	Start-up time <sup>(2)</sup>		200		μs

- (1) Probing or otherwise stopping the crystal while the DC/DC converter is enabled may cause permanent damage to the device.
- (2) Start-up time using the TI-provided power driver. Start-up time may increase if driver is not used.
- (3) On-chip default connected capacitance including reference design parasitic capacitance. Connected internal capacitance is changed through software in the Customer Configuration section (CCFG).
- (4) Adjustable load capacitance is integrated into the device. External load capacitors are required for systems targeting compliance with certain regulations. See the device errata for further details.
- (5) The crystal manufacturer's specification must satisfy this requirement for proper operation.

#### 7.14.3.2 48MHz RC Oscillator (RCOSC\_HF)

Measured on a Texas Instruments reference design with  $T_c = 25^\circ C$ ,  $V_{DDS} = 3.0V$ , unless otherwise noted.

	MIN	TYP	MAX	UNIT
Frequency	48			MHz
Uncalibrated frequency accuracy	±1			%

### 7.14.3.2 48MHz RC Oscillator (RCOSC\_HF) (续)

Measured on a Texas Instruments reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ , unless otherwise noted.

	MIN	TYP	MAX	UNIT
Calibrated frequency accuracy <sup>(1)</sup>		$\pm 0.25$		%
Start-up time		5		$\mu\text{s}$

(1) Accuracy relative to the calibration source (XOSC\_HF)

### 7.14.3.3 2MHz RC Oscillator (RCOSC\_MF)

Measured on a Texas Instruments reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ , unless otherwise noted.

	MIN	TYP	MAX	UNIT
Calibrated frequency		2		MHz
Start-up time		5		$\mu\text{s}$

### 7.14.3.4 32.768kHz Crystal Oscillator (XOSC\_LF)

Measured on a Texas Instruments reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ , unless otherwise noted.

	MIN	TYP	MAX	UNIT
Crystal frequency		32.768		kHz
ESR		30	100	$\text{k}\Omega$
$C_L$	6	7 <sup>(1)</sup>	12	pF

(1) Default load capacitance using TI reference designs including parasitic capacitance. Crystals with different load capacitance may be used.

### 7.14.3.5 32kHz RC Oscillator (RCOSC\_LF)

Measured on a Texas Instruments reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ , unless otherwise noted.

	MIN	TYP	MAX	UNIT
Calibrated frequency		32.8 <sup>(1)</sup>		kHz
Temperature coefficient.		50		ppm/ $^\circ\text{C}$

(1) When using RCOSC\_LF as source for the low frequency system clock (SCLK\_LF), the accuracy of the SCLK\_LF-derived Real Time Clock (RTC) can be improved by measuring RCOSC\_LF relative to XOSC\_HF and compensating for the RTC tick speed. This functionality is available through the TI-provided Power driver.

## 7.14.4 Synchronous Serial Interface (SSI) Characteristics

### 7.14.4.1 Synchronous Serial Interface (SSI) Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER NO.	PARAMETER		MIN	TYP	MAX	UNIT
S1	$t_{\text{clk\_per}}$	SSIClk cycle time	12	65024		System Clocks <sup>(2)</sup>
S2 <sup>(1)</sup>	$t_{\text{clk\_high}}$	SSIClk high time		0.5		$t_{\text{clk\_per}}$
S3 <sup>(1)</sup>	$t_{\text{clk\_low}}$	SSIClk low time		0.5		$t_{\text{clk\_per}}$

(1) Refer to SSI timing diagrams [Diagram 1](#), [Diagram 2](#), [Diagram 3](#)  
 (2) When using the TI-provided Power driver, the SSI system clock is always 48MHz.

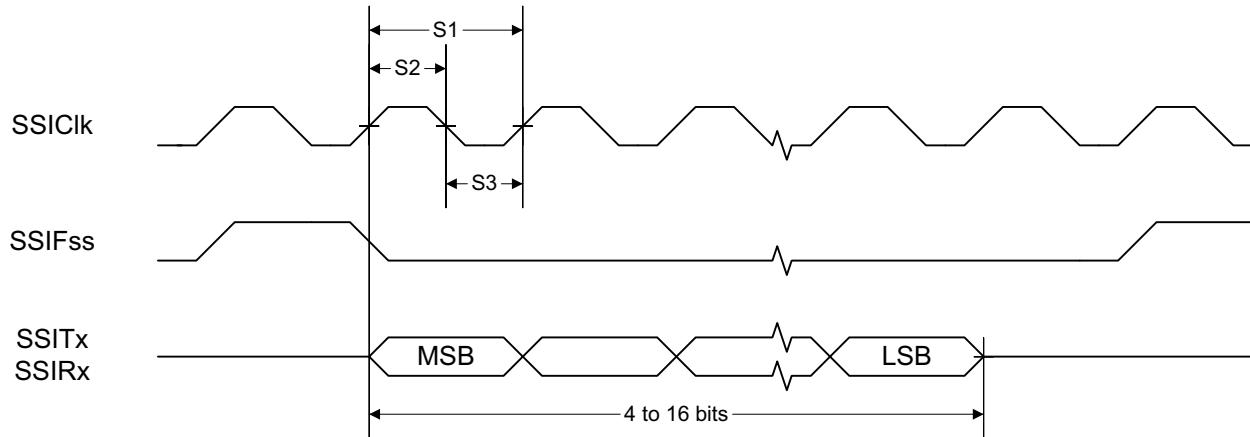


图 7-1. SSI Timing for TI Frame Format (FRF = 01), Single Transfer Timing Measurement

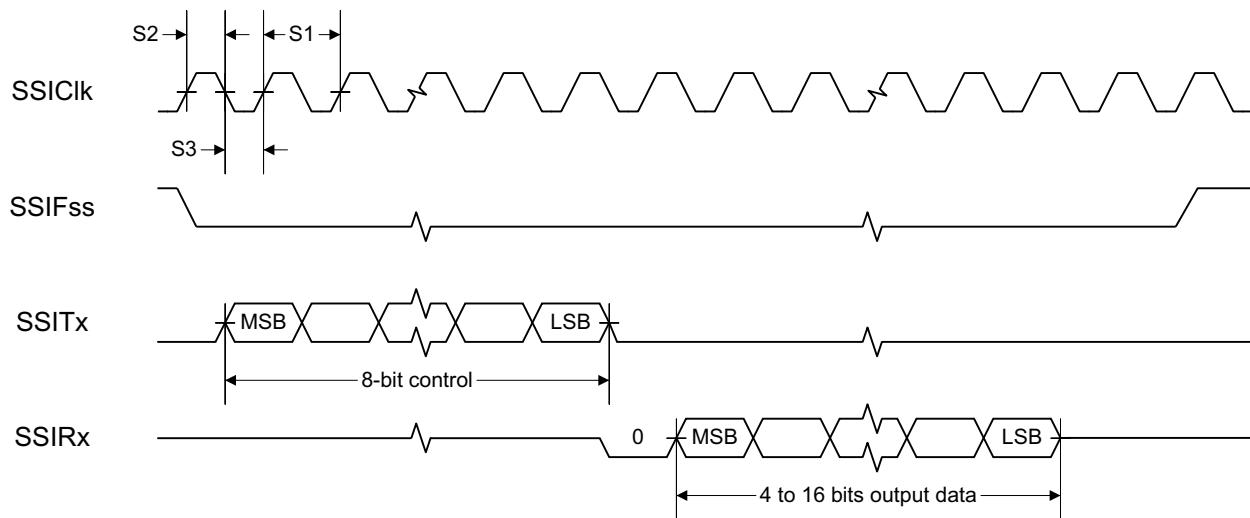


图 7-2. SSI Timing for MICROWIRE Frame Format (FRF = 10), Single Transfer

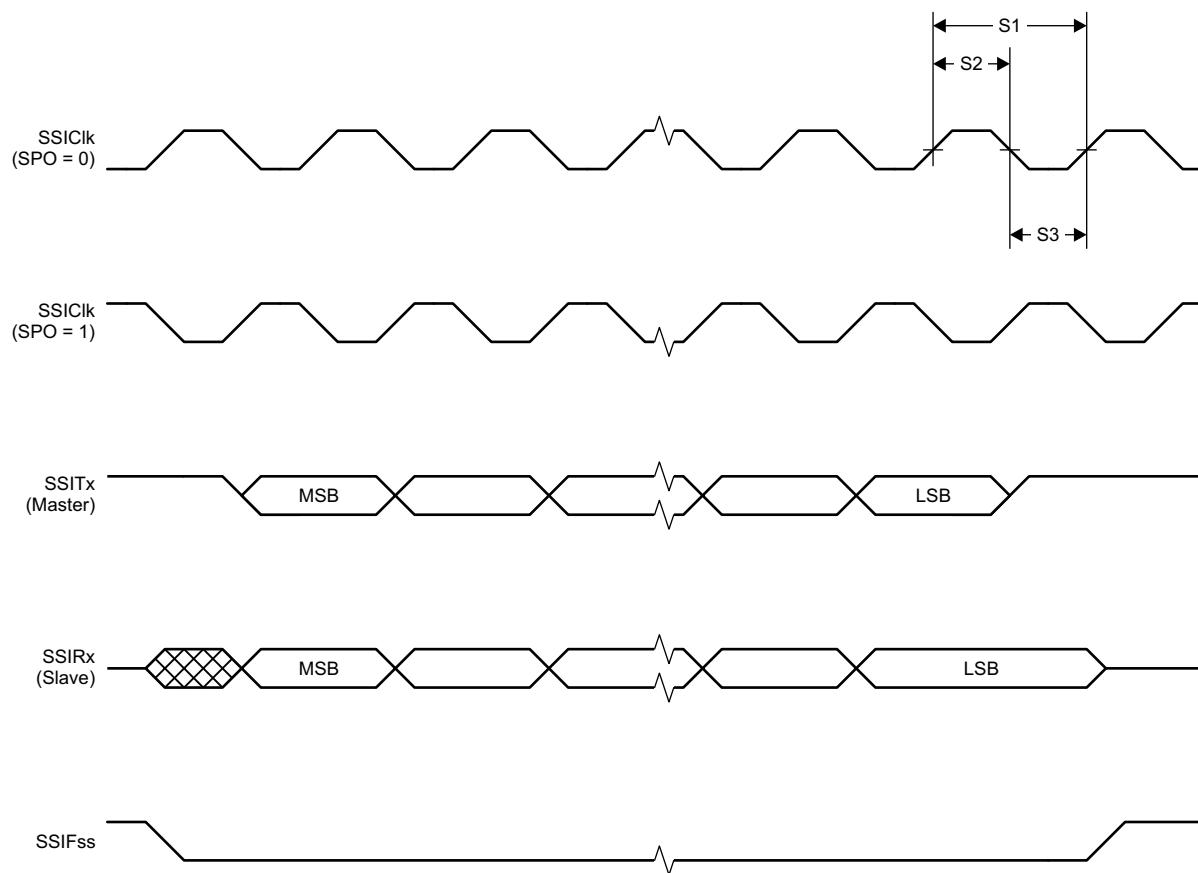


图 7-3. SSI Timing for SPI Frame Format (FRF = 00), With SPH = 1

## 7.14.5 UART

### 7.14.5.1 UART Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	MIN	TYP	MAX	UNIT
UART rate			3	MBaud

## 7.15 Peripheral Characteristics

### 7.15.1 ADC

#### 7.15.1.1 Analog-to-Digital Converter (ADC) Characteristics

$T_c = 25^\circ\text{C}$ ,  $V_{DD} = 3.0\text{V}$  and voltage scaling enabled, unless otherwise noted.<sup>(1)</sup>

Performance numbers require use of offset and gain adjustments in software by TI-provided ADC drivers.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input voltage range		0	$V_{DD}$		V
Resolution			12		Bits
Sample Rate			200		ksps
Offset	Internal 4.3V equivalent reference <sup>(2)</sup>		- 0.24		LSB
Gain error	Internal 4.3V equivalent reference <sup>(2)</sup>		7.14		LSB
DNL <sup>(4)</sup>	Differential nonlinearity		> - 1		LSB
INL	Integral nonlinearity		±4		LSB
ENOB	Effective number of bits	Internal 4.3V equivalent reference <sup>(2)</sup> , 200 kSamples/s, 9.6kHz input tone	9.8		Bits
		Internal 4.3V equivalent reference <sup>(2)</sup> , 200 kSamples/s, 9.6kHz input tone, DC/DC enabled	9.8		
		$V_{DD}$ as reference, 200 kSamples/s, 9.6kHz input tone	10.1		
		Internal reference, voltage scaling disabled, 32 samples average, 200 kSamples/s, 300 Hz input tone	11.1		
		Internal reference, voltage scaling disabled, 14-bit mode, 200 kSamples/s, 600 Hz input tone <sup>(5)</sup>	11.3		
		Internal reference, voltage scaling disabled, 15-bit mode, 200 kSamples/s, 150 Hz input tone <sup>(5)</sup>	11.6		
THD	Total harmonic distortion	Internal 4.3V equivalent reference <sup>(2)</sup> , 200 kSamples/s, 9.6kHz input tone	- 65		dB
		$V_{DD}$ as reference, 200 kSamples/s, 9.6kHz input tone	- 70		
		Internal reference, voltage scaling disabled, 32 samples average, 200 kSamples/s, 300 Hz input tone	- 72		
SINAD, SNDR	Signal-to-noise and distortion ratio	Internal 4.3V equivalent reference <sup>(2)</sup> , 200 kSamples/s, 9.6kHz input tone	60		dB
		$V_{DD}$ as reference, 200 kSamples/s, 9.6kHz input tone	63		
		Internal reference, voltage scaling disabled, 32 samples average, 200 kSamples/s, 300 Hz input tone	68		
SFDR	Spurious-free dynamic range	Internal 4.3V equivalent reference <sup>(2)</sup> , 200 kSamples/s, 9.6kHz input tone	70		dB
		$V_{DD}$ as reference, 200 kSamples/s, 9.6kHz input tone	73		
		Internal reference, voltage scaling disabled, 32 samples average, 200 kSamples/s, 300 Hz input tone	75		
Conversion time	Serial conversion, time-to-output, 24MHz clock	50			Clock Cycles
Current consumption	Internal 4.3V equivalent reference <sup>(2)</sup>	0.42			mA
Current consumption	$V_{DD}$ as reference	0.6			mA
Reference voltage	Equivalent fixed internal reference (input voltage scaling enabled). For best accuracy, the ADC conversion should be initiated through the TI-RTOS API in order to include the gain/offset compensation factors stored in FCFG1		4.3 <sup>(2) (3)</sup>		V
Reference voltage	Fixed internal reference (input voltage scaling disabled). For best accuracy, the ADC conversion should be initiated through the TI-RTOS API in order to include the gain/offset compensation factors stored in FCFG1. This value is derived from the scaled value (4.3V) as follows: $V_{ref} = 4.3V \times 1408 / 4095$		1.48		V
Reference voltage	$V_{DD}$ as reference, input voltage scaling enabled		$V_{DD}$		V
Reference voltage	$V_{DD}$ as reference, input voltage scaling disabled		$V_{DD} / 2.82^{(3)}$		V

### 7.15.1.1 Analog-to-Digital Converter (ADC) Characteristics (续)

$T_c = 25^\circ\text{C}$ ,  $V_{DDS} = 3.0\text{V}$  and voltage scaling enabled, unless otherwise noted.<sup>(1)</sup>

Performance numbers require use of offset and gain adjustments in software by TI-provided ADC drivers.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input impedance	200 kSamples/s, voltage scaling enabled. Capacitive input, Input impedance depends on sampling frequency and sampling time		>1		$\text{M}\Omega$

- (1) Using IEEE Std 1241-2010 for terminology and test methods
- (2) Input signal scaled down internally before conversion, as if voltage range was 0 to 4.3V
- (3) Applied voltage must be within Absolute Maximum Ratings (see [节 7.1](#)) at all times
- (4) No missing codes
- (5)  $\text{ADC\_output} = \sum (4^n \text{ samples}) \gg n$ ,  $n$  = desired extra bits

### 7.15.2 DAC

#### 7.15.2.1 Digital-to-Analog Converter (DAC) Characteristics

$T_c = 25^\circ\text{C}$ ,  $V_{DDS} = 3.0\text{V}$ , unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>General Parameters</b>					
	Resolution		8		Bits
$V_{DDS}$	Supply voltage	Any load, any $V_{REF}$ , precharge OFF, DAC charge-pump ON	1.8	3.8	V
		External Load <sup>(4)</sup> , any $V_{REF}$ , precharge OFF, DAC charge-pump OFF	2.0	3.8	
		Any load, $V_{REF} = \text{DCOUP}$ , precharge ON	2.6	3.8	
$F_{DAC}$	Clock frequency	Buffer ON (recommended for external load)	16	250	kHz
		Buffer OFF (internal load)	16	1000	
	Voltage output settling time	$V_{REF} = V_{DDS}$ , buffer OFF, internal load	13		$1 / F_{DAC}$
		$V_{REF} = V_{DDS}$ , buffer ON, external capacitive load = $20\text{pF}$ <sup>(3)</sup>		13.8	
	External capacitive load		20	200	pF
	External resistive load		10		$\text{M}\Omega$
	Short circuit current			400	$\mu\text{A}$
$Z_{MAX}$	Max output impedance $V_{ref} = V_{DDS}$ , buffer ON, CLK 250kHz <sup>(5)</sup>	$V_{DDS} = 3.8\text{V}$ , DAC charge-pump OFF	50.8		$\text{k}\Omega$
		$V_{DDS} = 3.0\text{V}$ , DAC charge-pump ON	51.7		
		$V_{DDS} = 3.0\text{V}$ , DAC charge-pump OFF	53.2		
		$V_{DDS} = 2.0\text{V}$ , DAC charge-pump ON	48.7		
		$V_{DDS} = 2.0\text{V}$ , DAC charge-pump OFF	70.2		
		$V_{DDS} = 1.8\text{V}$ , DAC charge-pump ON	46.3		
		$V_{DDS} = 1.8\text{V}$ , DAC charge-pump OFF	88.9		
<b>Internal Load - Continuous Time Comparator / Low Power Clocked Comparator</b>					
DNL	Differential nonlinearity	$V_{REF} = V_{DDS}$ , load = Continuous Time Comparator or Low Power Clocked Comparator $F_{DAC} = 250\text{kHz}$	$\pm 1$		LSB <sup>(1)</sup>
	Differential nonlinearity	$V_{REF} = V_{DDS}$ , load = Continuous Time Comparator or Low Power Clocked Comparator $F_{DAC} = 16\text{kHz}$	$\pm 1.2$		
	Offset error <sup>(2)</sup> Load = Continuous Time Comparator	$V_{REF} = V_{DDS} = 3.8\text{V}$	$\pm 0.64$		LSB <sup>(1)</sup>
		$V_{REF} = V_{DDS} = 3.0\text{V}$	$\pm 0.81$		
		$V_{REF} = V_{DDS} = 1.8\text{V}$	$\pm 1.27$		
		$V_{REF} = \text{DCOUP}$ , precharge ON	$\pm 3.43$		
		$V_{REF} = \text{DCOUP}$ , precharge OFF	$\pm 2.88$		
		$V_{REF} = \text{ADCREF}$	$\pm 2.37$		

### 7.15.2.1 Digital-to-Analog Converter (DAC) Characteristics (续)

$T_c = 25^\circ\text{C}$ ,  $V_{DDS} = 3.0\text{V}$ , unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Offset error <sup>(2)</sup> Load = Low Power Clocked Comparator	$V_{REF} = V_{DDS} = 3.8\text{V}$	±0.78			LSB <sup>(1)</sup>
	$V_{REF} = V_{DDS} = 3.0\text{V}$	±0.77			
	$V_{REF} = V_{DDS} = 1.8\text{V}$	±3.46			
	$V_{REF} = \text{DCOUPL}$ , precharge ON	±3.44			
	$V_{REF} = \text{DCOUPL}$ , precharge OFF	±4.70			
	$V_{REF} = \text{ADCREF}$	±4.11			
Max code output voltage variation <sup>(2)</sup> Load = Continuous Time Comparator	$V_{REF} = V_{DDS} = 3.8\text{V}$	±1.53			LSB <sup>(1)</sup>
	$V_{REF} = V_{DDS} = 3.0\text{V}$	±1.71			
	$V_{REF} = V_{DDS} = 1.8\text{V}$	±2.10			
	$V_{REF} = \text{DCOUPL}$ , precharge ON	±6.00			
	$V_{REF} = \text{DCOUPL}$ , precharge OFF	±3.85			
	$V_{REF} = \text{ADCREF}$	±5.84			
Max code output voltage variation <sup>(2)</sup> Load = Low Power Clocked Comparator	$V_{REF} = V_{DDS} = 3.8\text{V}$	±2.92			LSB <sup>(1)</sup>
	$V_{REF} = V_{DDS} = 3.0\text{V}$	±3.06			
	$V_{REF} = V_{DDS} = 1.8\text{V}$	±3.91			
	$V_{REF} = \text{DCOUPL}$ , precharge ON	±7.84			
	$V_{REF} = \text{DCOUPL}$ , precharge OFF	±4.06			
	$V_{REF} = \text{ADCREF}$	±6.94			
Output voltage range <sup>(2)</sup> Load = Continuous Time Comparator	$V_{REF} = V_{DDS} = 3.8\text{V}$ , code 1	0.03			V
	$V_{REF} = V_{DDS} = 3.8\text{V}$ , code 255	3.62			
	$V_{REF} = V_{DDS} = 3.0\text{V}$ , code 1	0.02			
	$V_{REF} = V_{DDS} = 3.0\text{V}$ , code 255	2.86			
	$V_{REF} = V_{DDS} = 1.8\text{V}$ , code 1	0.01			
	$V_{REF} = V_{DDS} = 1.8\text{V}$ , code 255	1.71			
	$V_{REF} = \text{DCOUPL}$ , precharge OFF, code 1	0.01			
	$V_{REF} = \text{DCOUPL}$ , precharge OFF, code 255	1.21			
	$V_{REF} = \text{DCOUPL}$ , precharge ON, code 1	1.27			
	$V_{REF} = \text{DCOUPL}$ , precharge ON, code 255	2.46			
	$V_{REF} = \text{ADCREF}$ , code 1	0.01			
	$V_{REF} = \text{ADCREF}$ , code 255	1.41			
Output voltage range <sup>(2)</sup> Load = Low Power Clocked Comparator	$V_{REF} = V_{DDS} = 3.8\text{V}$ , code 1	0.03			V
	$V_{REF} = V_{DDS} = 3.8\text{V}$ , code 255	3.61			
	$V_{REF} = V_{DDS} = 3.0\text{V}$ , code 1	0.02			
	$V_{REF} = V_{DDS} = 3.0\text{V}$ , code 255	2.85			
	$V_{REF} = V_{DDS} = 1.8\text{V}$ , code 1	0.01			
	$V_{REF} = V_{DDS} = 1.8\text{V}$ , code 255	1.71			
	$V_{REF} = \text{DCOUPL}$ , precharge OFF, code 1	0.01			
	$V_{REF} = \text{DCOUPL}$ , precharge OFF, code 255	1.21			
	$V_{REF} = \text{DCOUPL}$ , precharge ON, code 1	1.27			
	$V_{REF} = \text{DCOUPL}$ , precharge ON, code 255	2.46			
	$V_{REF} = \text{ADCREF}$ , code 1	0.01			
	$V_{REF} = \text{ADCREF}$ , code 255	1.41			
<b>External Load (Keysight 34401A Multimeter)</b>					
INL	Integral nonlinearity	$V_{REF} = V_{DDS}$ , $F_{DAC} = 250\text{kHz}$	±1		LSB <sup>(1)</sup>
		$V_{REF} = \text{DCOUPL}$ , $F_{DAC} = 250\text{kHz}$	±1		
		$V_{REF} = \text{ADCREF}$ , $F_{DAC} = 250\text{kHz}$	±1		
DNL	Differential nonlinearity	$V_{REF} = V_{DDS}$ , $F_{DAC} = 250\text{kHz}$	±1		LSB <sup>(1)</sup>

### 7.15.2.1 Digital-to-Analog Converter (DAC) Characteristics (续)

$T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ , unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
DAC Offset error	$V_{\text{REF}} = V_{\text{DDS}} = 3.8\text{V}$	±0.40			LSB <sup>(1)</sup>
	$V_{\text{REF}} = V_{\text{DDS}} = 3.0\text{V}$	±0.50			
	$V_{\text{REF}} = V_{\text{DDS}} = 1.8\text{V}$	±0.75			
	$V_{\text{REF}} = \text{DCOUP}, \text{precharge ON}$	±1.55			
	$V_{\text{REF}} = \text{DCOUP}, \text{precharge OFF}$	±1.30			
	$V_{\text{REF}} = \text{ADCREF}$	±1.10			
DAC Max code output voltage variation	$V_{\text{REF}} = V_{\text{DDS}} = 3.8\text{V}$	±1.00			LSB <sup>(1)</sup>
	$V_{\text{REF}} = V_{\text{DDS}} = 3.0\text{V}$	±1.00			
	$V_{\text{REF}} = V_{\text{DDS}} = 1.8\text{V}$	±1.00			
	$V_{\text{REF}} = \text{DCOUP}, \text{precharge ON}$	±3.45			
	$V_{\text{REF}} = \text{DCOUP}, \text{precharge OFF}$	±2.10			
	$V_{\text{REF}} = \text{ADCREF}$	±1.90			
Output voltage range Load = Low Power Clocked Comparator	$V_{\text{REF}} = V_{\text{DDS}} = 3.8\text{V}, \text{code 1}$	0.03			V
	$V_{\text{REF}} = V_{\text{DDS}} = 3.8\text{V}, \text{code 255}$	3.61			
	$V_{\text{REF}} = V_{\text{DDS}} = 3.0\text{V}, \text{code 1}$	0.02			
	$V_{\text{REF}} = V_{\text{DDS}} = 3.0\text{V}, \text{code 255}$	2.85			
	$V_{\text{REF}} = V_{\text{DDS}} = 1.8\text{V}, \text{code 1}$	0.02			
	$V_{\text{REF}} = V_{\text{DDS}} = 1.8\text{V}, \text{code 255}$	1.71			
	$V_{\text{REF}} = \text{DCOUP}, \text{precharge OFF, code 1}$	0.02			
	$V_{\text{REF}} = \text{DCOUP}, \text{precharge OFF, code 255}$	1.20			
	$V_{\text{REF}} = \text{DCOUP}, \text{precharge ON, code 1}$	1.27			
	$V_{\text{REF}} = \text{DCOUP}, \text{precharge ON, code 255}$	2.46			
	$V_{\text{REF}} = \text{ADCREF, code 1}$	0.02			
	$V_{\text{REF}} = \text{ADCREF, code 255}$	1.42			

(1) 1 LSB ( $V_{\text{REF}} 3.8\text{V}/3.0\text{V}/1.8\text{V}/\text{DCOUP}/\text{ADCREF}$ ) =  $14.10\text{mV}/11.13\text{mV}/6.68\text{mV}/4.67\text{mV}/5.48\text{mV}$

(2) Includes comparator offset

(3) A load > 20pF will increase the settling time

(4) Keysight 34401A Multimeter

(5) When using lower levels of  $V_{\text{DDS}}$  with the charge pump OFF, care must be taken to adapt the surrounding circuit to the increase in impedance.

### 7.15.3 Temperature and Battery Monitor

#### 7.15.3.1 Temperature Sensor

Measured on a Texas Instruments reference design with  $T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ , unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Resolution			2		$^\circ\text{C}$
Accuracy	-40 $^\circ\text{C}$ to 0 $^\circ\text{C}$		$\pm 4.0$		$^\circ\text{C}$
Accuracy	0 $^\circ\text{C}$ to 85 $^\circ\text{C}$		$\pm 2.5$		$^\circ\text{C}$
Supply voltage coefficient <sup>(1)</sup>			3.6		$^\circ\text{C}/\text{V}$

(1) The temperature sensor is automatically compensated for VDDS variation when using the TI-provided driver.

#### 7.15.3.2 Battery Monitor

Measured on a Texas Instruments reference design with  $T_c = 25^\circ\text{C}$ , unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Resolution			25		mV
Range		1.8		3.8	V
Integral nonlinearity (max)			23		mV
Accuracy	VDDS = 3.0V		22.5		mV
Offset error			-32		mV
Gain error			-1		%

### 7.15.4 Comparators

#### 7.15.4.1 Low-Power Clocked Comparator

$T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ , unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input voltage range		0		$V_{\text{DDS}}$	V
Clock frequency				SCLK_LF	
Internal reference voltage <sup>(1)</sup>	Using internal DAC with $V_{\text{DDS}}$ as reference voltage, DAC code = 0 - 255		0.024 - 2.865		V
Offset	Measured at $V_{\text{DDS}} / 2$ , includes error from internal DAC		$\pm 5$		mV
Decision time	Step from - 50mV to 50mV		1		Clock Cycle

(1) The comparator can use an internal 8 bits DAC as its reference. The DAC output voltage range depends on the reference voltage selected. See [节 7.15.2.1](#)

#### 7.15.4.2 Continuous Time Comparator

$T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ , unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input voltage range <sup>(1)</sup>		0		$V_{\text{DDS}}$	V
Offset	Measured at $V_{\text{DDS}} / 2$		$\pm 5$		mV
Decision time	Step from - 10mV to 10mV		0.78		$\mu\text{s}$
Current consumption	Internal reference		8.6		$\mu\text{A}$

(1) The input voltages can be generated externally and connected throughout I/Os or an internal reference voltage can be generated using the DAC

### 7.15.5 Current Source

#### 7.15.5.1 Programmable Current Source

$T_c = 25^\circ\text{C}$ ,  $V_{\text{DDS}} = 3.0\text{V}$ , unless otherwise noted.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Current source programmable output range (logarithmic range)			0.25 - 20		$\mu\text{A}$
Resolution			0.25		$\mu\text{A}$

## 7.15.6 GPIO

### 7.15.6.1 GPIO DC Characteristics

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b><math>T_A = 25^\circ\text{C}</math>, <math>V_{DDS} = 1.8\text{V}</math></b>					
GPIO VOH at 8 mA load	IOCURR = 2, high-drive GPIOs only	1.56			V
GPIO VOL at 8 mA load	IOCURR = 2, high-drive GPIOs only	0.24			V
GPIO VOH at 4 mA load	IOCURR = 1	1.59			V
GPIO VOL at 4 mA load	IOCURR = 1	0.21			V
GPIO pullup current	Input mode, pullup enabled, $V_{pad} = 0\text{V}$	73			$\mu\text{A}$
GPIO pulldown current	Input mode, pulldown enabled, $V_{pad} = V_{DDS}$	19			$\mu\text{A}$
GPIO low-to-high input transition, with hysteresis	$I_{IH} = 1$ , transition voltage for input read as $0 \rightarrow 1$	1.08			V
GPIO high-to-low input transition, with hysteresis	$I_{IH} = 1$ , transition voltage for input read as $1 \rightarrow 0$	0.73			V
GPIO input hysteresis	$I_{IH} = 1$ , difference between $0 \rightarrow 1$ and $1 \rightarrow 0$ points	0.35			V
<b><math>T_A = 25^\circ\text{C}</math>, <math>V_{DDS} = 3.0\text{V}</math></b>					
GPIO VOH at 8 mA load	IOCURR = 2, high-drive GPIOs only	2.59			V
GPIO VOL at 8 mA load	IOCURR = 2, high-drive GPIOs only	0.42			V
GPIO VOH at 4 mA load	IOCURR = 1	2.63			V
GPIO VOL at 4 mA load	IOCURR = 1	0.40			V
<b><math>T_A = 25^\circ\text{C}</math>, <math>V_{DDS} = 3.8\text{V}</math></b>					
GPIO pullup current	Input mode, pullup enabled, $V_{pad} = 0\text{V}$	282			$\mu\text{A}$
GPIO pulldown current	Input mode, pulldown enabled, $V_{pad} = V_{DDS}$	110			$\mu\text{A}$
GPIO low-to-high input transition, with hysteresis	$I_{IH} = 1$ , transition voltage for input read as $0 \rightarrow 1$	1.97			V
GPIO high-to-low input transition, with hysteresis	$I_{IH} = 1$ , transition voltage for input read as $1 \rightarrow 0$	1.55			V
GPIO input hysteresis	$I_{IH} = 1$ , difference between $0 \rightarrow 1$ and $1 \rightarrow 0$ points	0.42			V
<b><math>T_A = 25^\circ\text{C}</math></b>					
VIH	Lowest GPIO input voltage reliably interpreted as a <i>High</i>	0.8* $V_{DDS}$			V
VIL	Highest GPIO input voltage reliably interpreted as a <i>Low</i>	0.2* $V_{DDS}$			V

## 7.16 Typical Characteristics

All measurements in this section are done with  $T_c = 25^\circ\text{C}$  and  $V_{DDS} = 3.0\text{V}$ , unless otherwise noted. See *Recommended Operating Conditions* for device limits. Values exceeding these limits are for reference only.

### 7.16.1 MCU Current

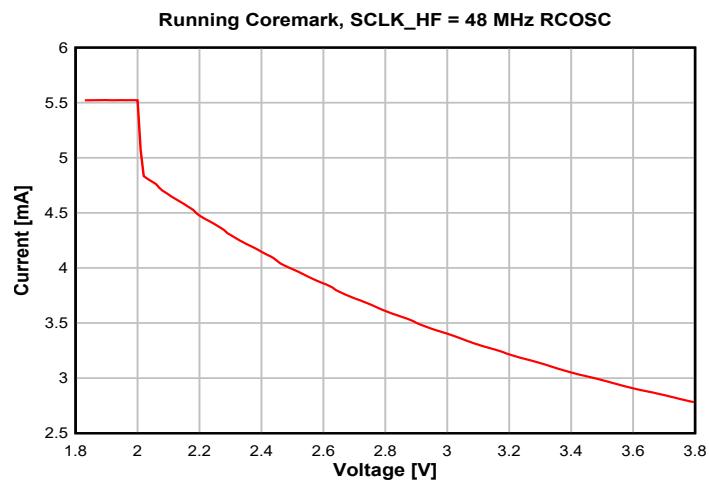


图 7-4. Active Mode (MCU) Current vs.  
Supply Voltage (VDDS)

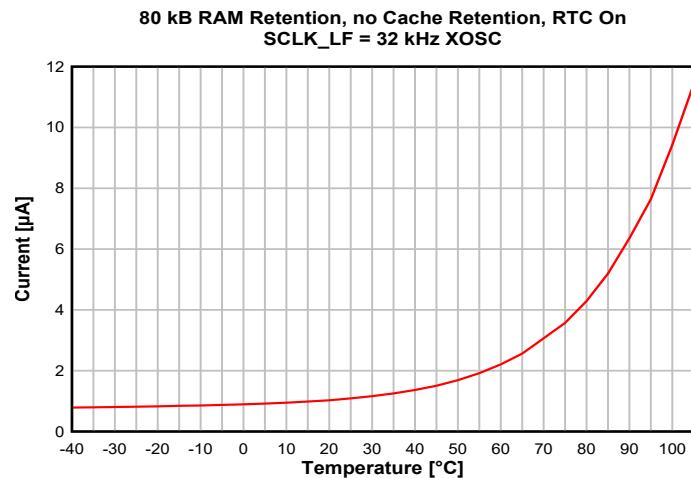


图 7-5. Standby Mode (MCU) Current vs.  
Temperature

### 7.16.2 RX Current

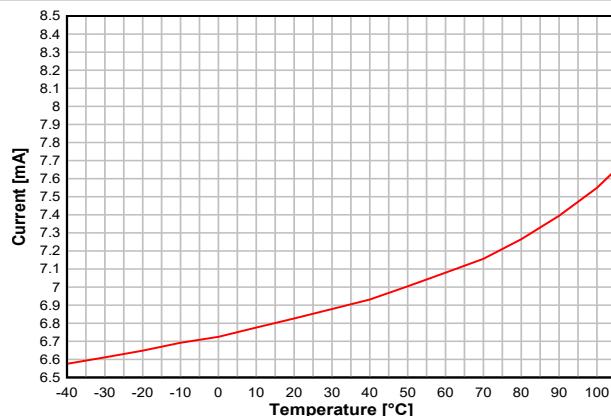


图 7-6. RX Current vs.  
Temperature (BLE 1Mbps, 2.44GHz)

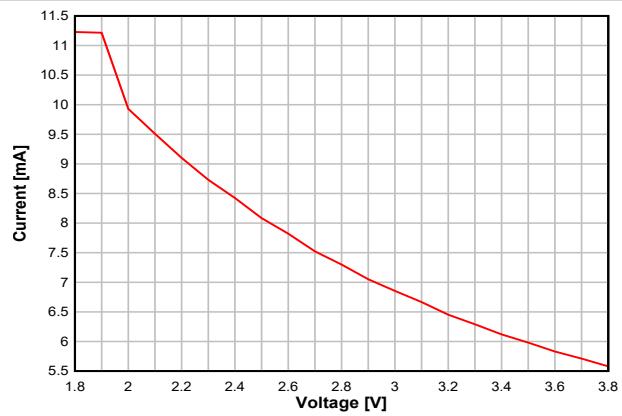


图 7-7. RX Current vs.  
Supply Voltage (VDD<sub>S</sub>) (BLE 1Mbps, 2.44GHz)

### 7.16.3 TX Current

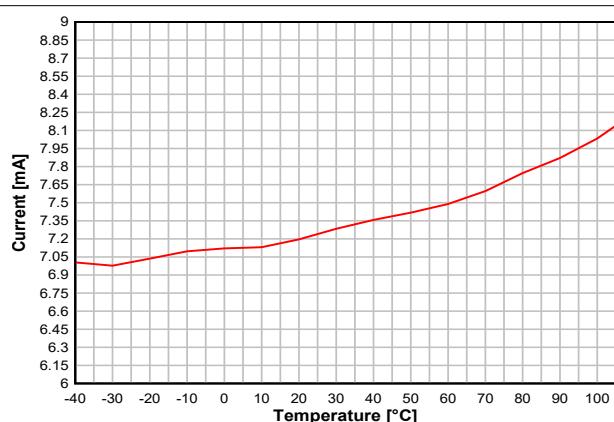


图 7-8. TX Current vs. Temperature (BLE 1Mbps, 2.44GHz, 0dBm)

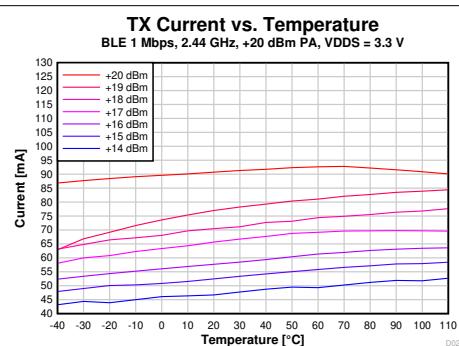


图 7-9. TX Current vs. Temperature (BLE 1Mbps, 2.44GHz, VDDS = 3.3V)

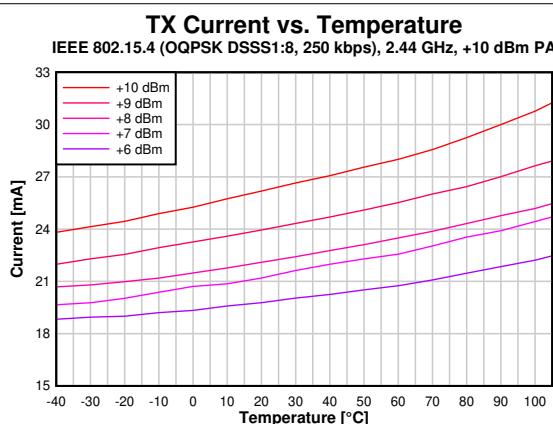


图 7-10. TX Current vs. Temperature (250kbps, 2.44GHz, +10dBm PA)

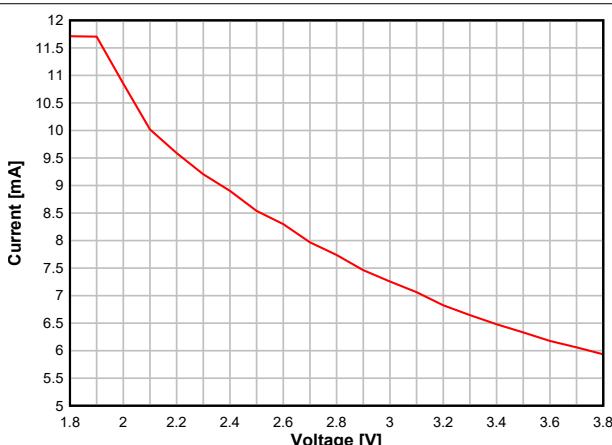


图 7-11. TX Current vs. Supply Voltage (VDDS) (BLE 1Mbps, 2.44GHz, 0dBm)

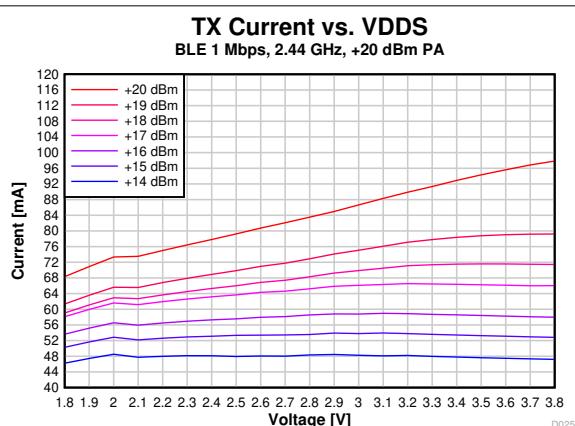


图 7-12. TX Current vs. Supply Voltage (VDDS) (BLE 1Mbps, 2.44GHz, +20dBm PA)

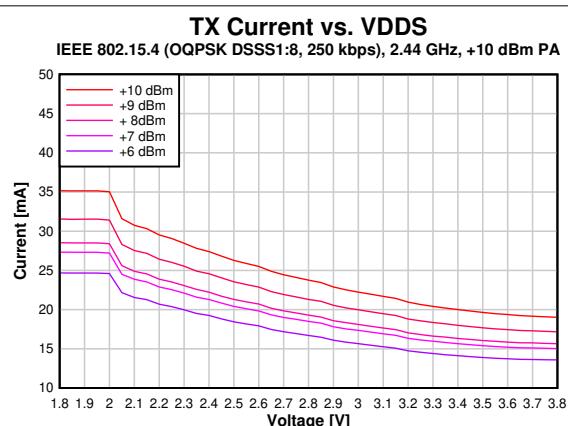


图 7-13. TX Current vs. Supply Voltage (VDDS) (250kbps, 2.44GHz, +10dBm PA)

表 7-1 shows typical TX current and output power for different output power settings.

**表 7-1. Typical TX Current and Output Power**

CC2652P at 2.4GHz, VDDS = 3.0V (Measured on CC1352PEM-XD7793-XD24-PA24)			
txPower	TX Power Setting (SmartRF Studio)	Typical Output Power [dBm]	Typical Current Consumption [mA]
0x7217	5	3.1	8.7
0x4E63	4	1.8	8.2
0x385D	3	0.5	7.7
0x3259	2	-0.7	7.3
0x2856	1	-1.8	6.9
0x2853	0	-3.1	6.6
0x12D6	-5	-7.7	5.8
0x0ACF	-10	-12.6	5.3
0x06CA	-15	-17.9	4.9
0x04C6	-20	-23.6	4.7

#### 7.16.4 RX Performance

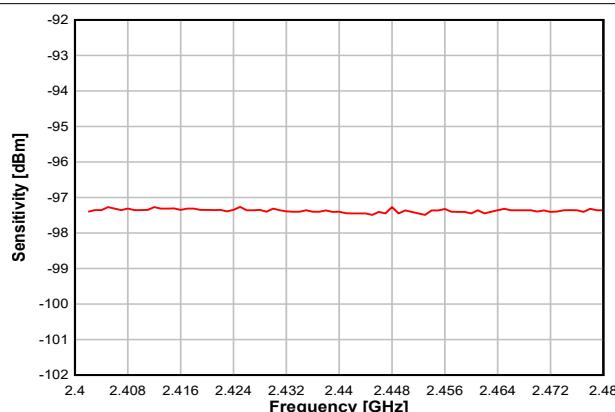


图 7-14. Sensitivity vs. Frequency (BLE 1Mbps, 2.44GHz)

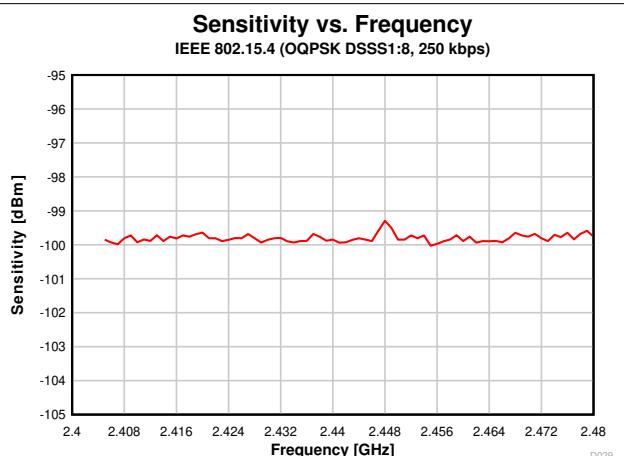


图 7-15. Sensitivity vs. Frequency (IEEE 802.15.4-2006, 250 kbps, OQPSK DSSS 1:8, 2.44GHz)

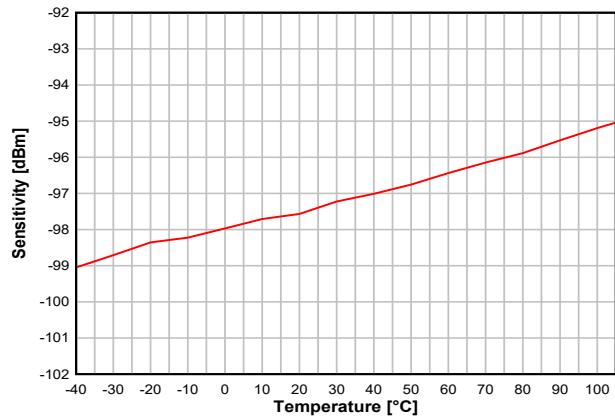


图 7-16. Sensitivity vs. Temperature (BLE 1Mbps, 2.44GHz)

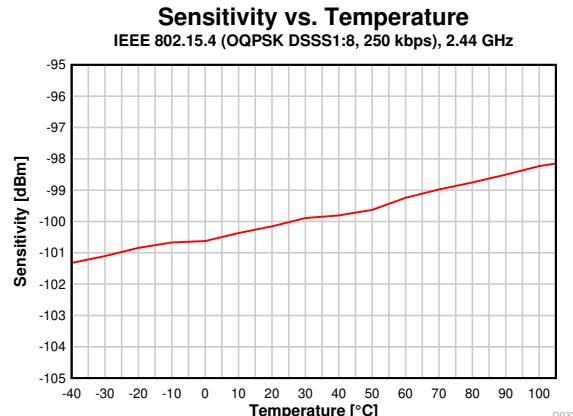


图 7-17. Sensitivity vs. Temperature (IEEE 802.15.4-2006, 250 kbps, OQPSK DSSS 1:8, 2.44GHz)

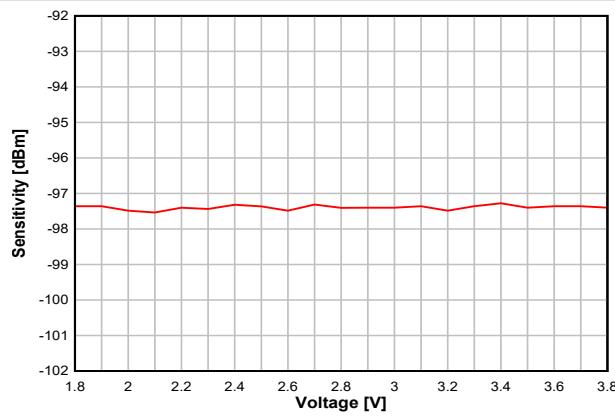


图 7-18. Sensitivity vs. Supply Voltage (VDDS) (BLE 1Mbps, 2.44GHz)

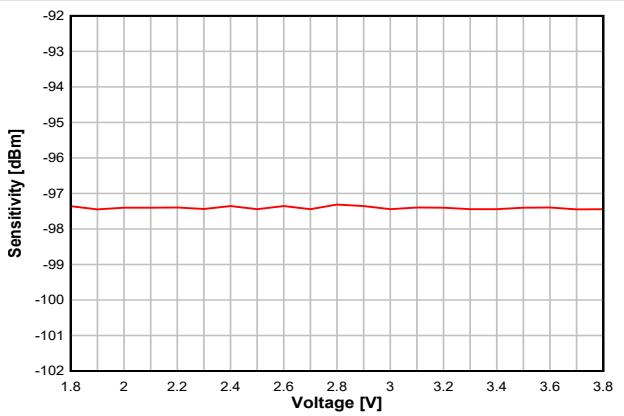


图 7-19. Sensitivity vs. Supply Voltage (VDDS) (BLE 1Mbps, 2.44GHz, DCDC Off)

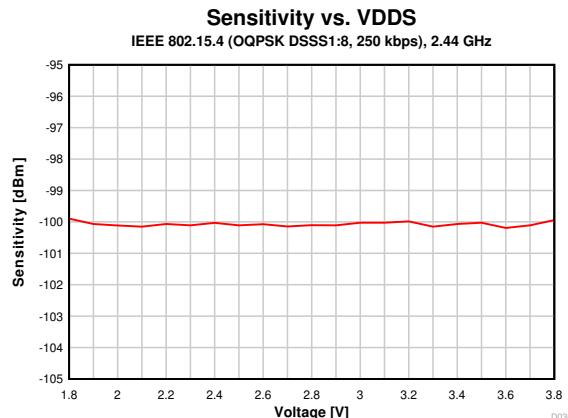


图 7-20. Sensitivity vs. Supply Voltage (VDDS) (IEEE 802.15.4-2006, 250 kbps, OQPSK DSSS 1:8, 2.44GHz)

### 7.16.5 TX Performance

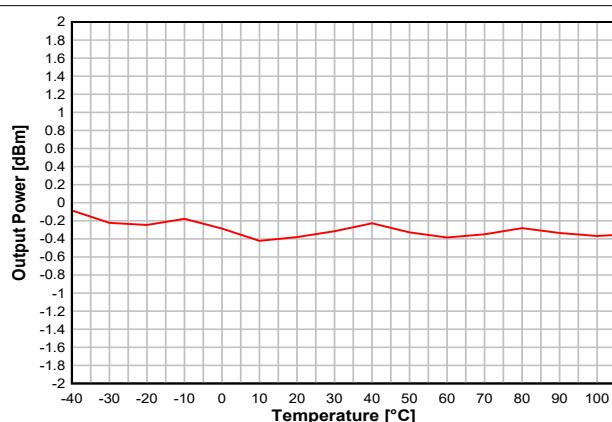


图 7-21. Output Power vs.  
Temperature (BLE 1Mbps, 2.44GHz, 0dBm)

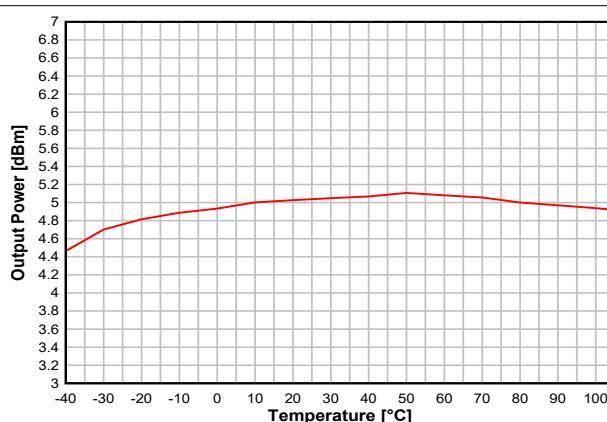


图 7-22. Output Power vs.  
Temperature (BLE 1Mbps, 2.44GHz, +5dBm)

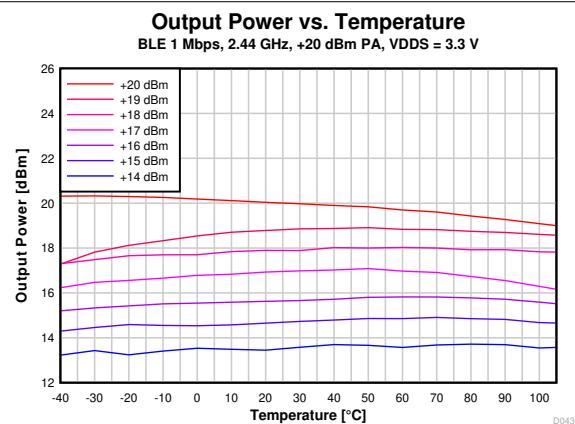


图 7-23. Output Power vs.  
Temperature (BLE 1Mbps, 2.44GHz, +20dBm PA)

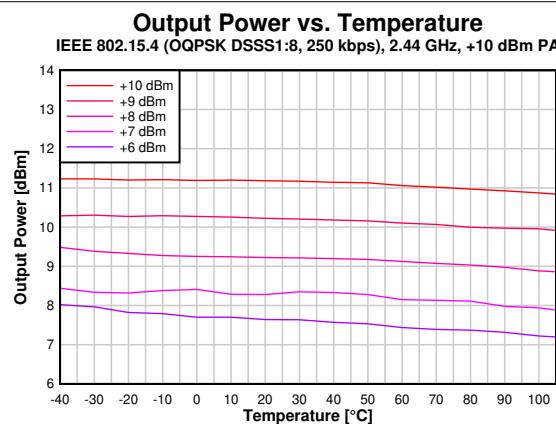


图 7-24. Output Power vs.  
Temperature (IEEE 802.15.4-2006, 250 kbps,  
OQPSK DSSS 1:8, 2.44GHz, +10dBm PA)

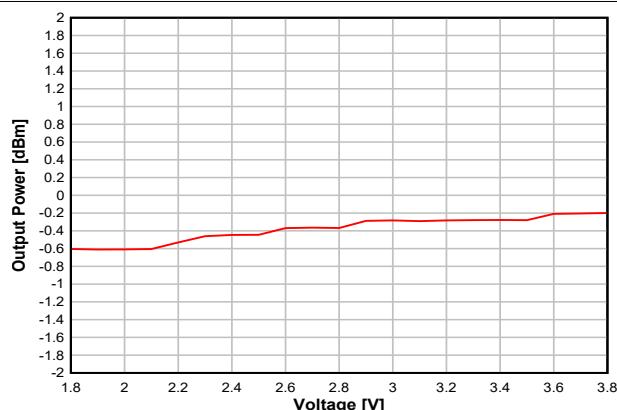


图 7-25. Output Power vs.  
Supply Voltage (VDDSS) (BLE 1 Mbps, 2.44GHz,  
0dBm)

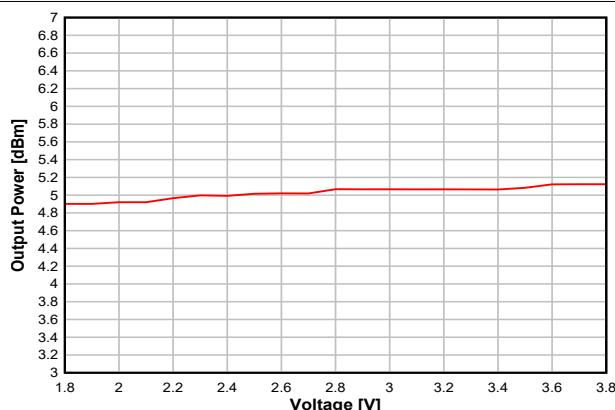


图 7-26. Output Power vs.  
Supply Voltage (VDDSS) (BLE 1 Mbps, 2.44GHz,  
+5dBm)

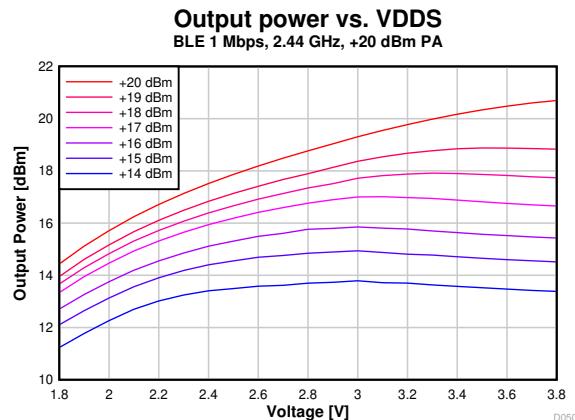


图 7-27. Output Power vs.  
Supply Voltage (VDDS) (BLE 1Mbps, 2.44GHz,  
+20dBm PA)

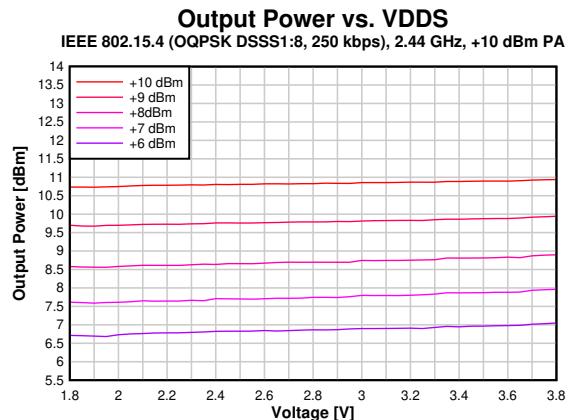


图 7-28. Output Power vs.  
Supply Voltage (VDDS) (IEEE 802.15.4-2006,  
250 kbps, OQPSK DSSS 1:8, 2.44GHz, +10dBm PA)

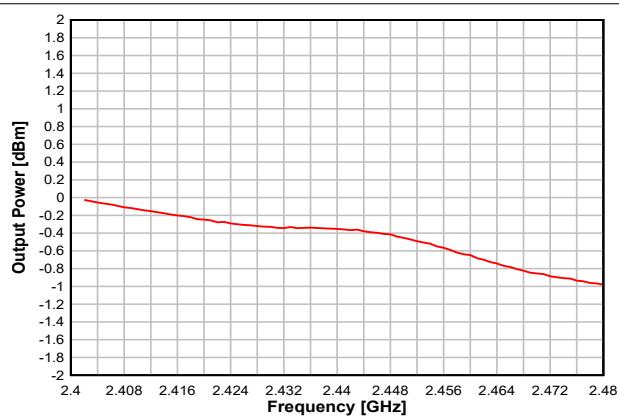


图 7-29. Output Power vs.  
Frequency (BLE 1Mbps, 2.44 GHz, 0dBm)

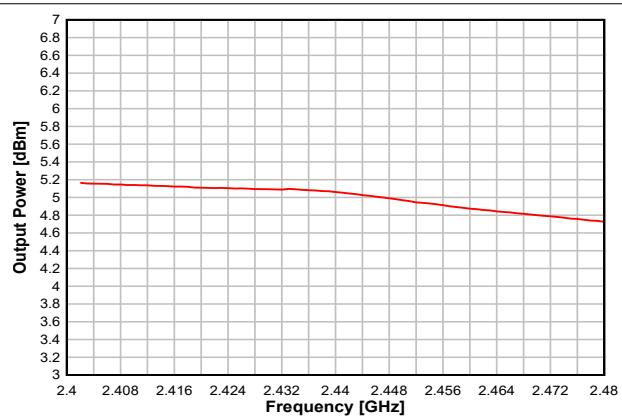


图 7-30. Output Power vs.  
Frequency (BLE 1Mbps, 2.44 GHz, +5dBm)

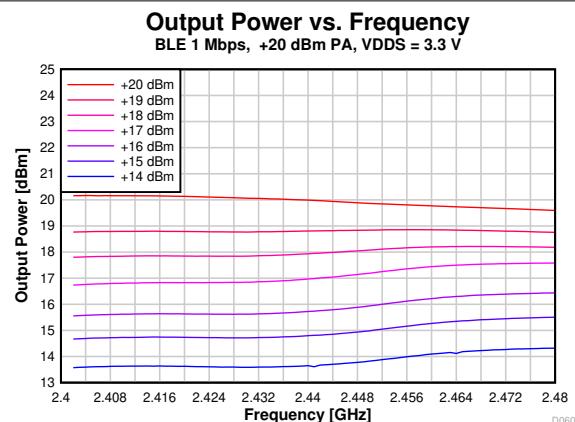


图 7-31. Output Power vs.  
Frequency (BLE 1Mbps, 2.44GHz, +20dBm PA)

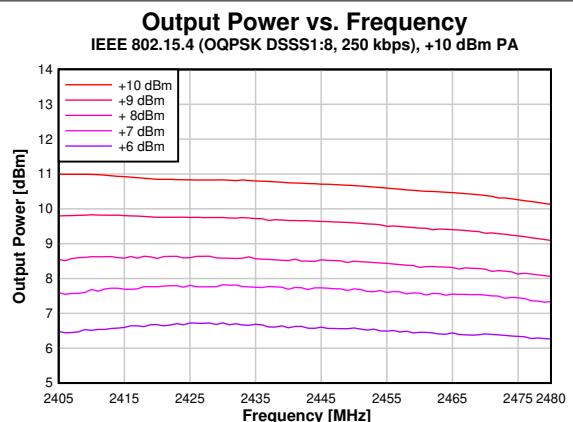


图 7-32. Output Power vs.  
Frequency (IEEE 802.15.4-2006, 250 kbps,  
OQPSK DSSS 1:8, 2.44GHz, +10dBm PA)

### 7.16.6 ADC Performance

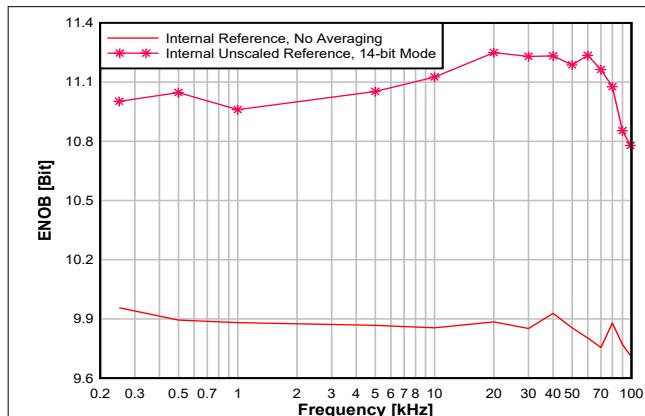


图 7-33. ENOB vs.  
Input Frequency

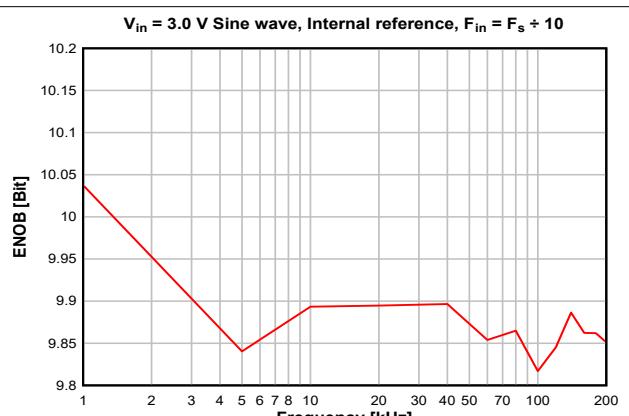


图 7-34. ENOB vs.  
Sampling Frequency

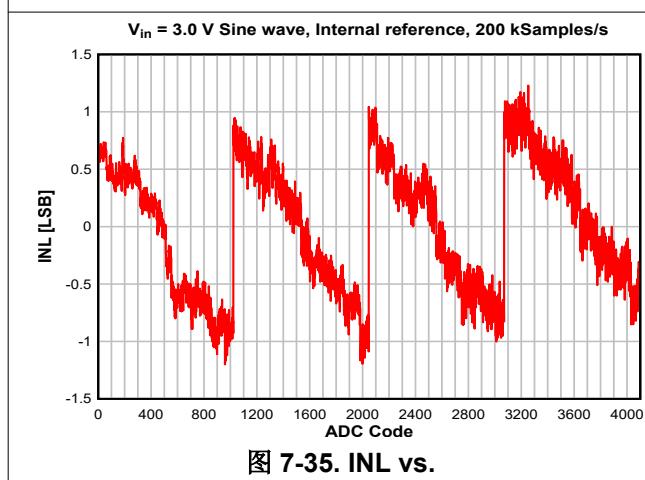


图 7-35. INL vs.  
ADC Code

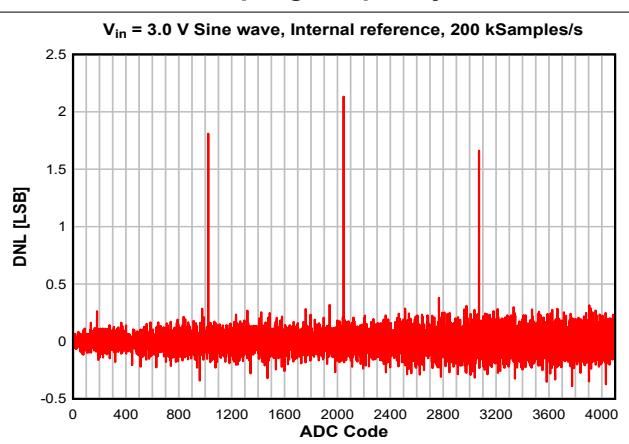


图 7-36. DNL vs.  
ADC Code

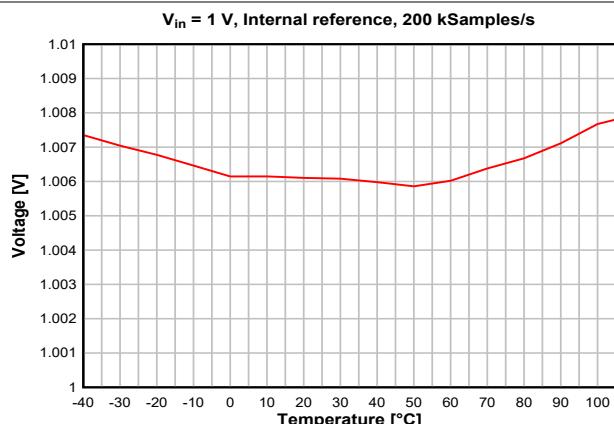


图 7-37. ADC Accuracy vs.  
Temperature

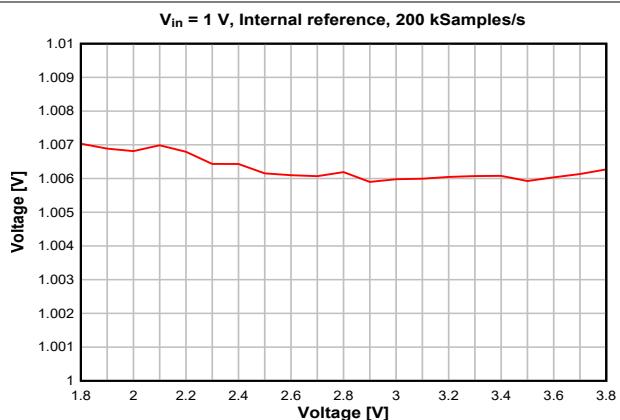


图 7-38. ADC Accuracy vs.  
Supply Voltage (VDDS)

## 8 Detailed Description

### 8.1 Overview

节 4 shows the core modules of the CC2652P device.

### 8.2 System CPU

The CC2652P SimpleLink™ Wireless MCU contains an Arm® Cortex®-M4F system CPU, which runs the application and the higher layers of radio protocol stacks.

The system CPU is the foundation of a high-performance, low-cost platform that meets the system requirements of minimal memory implementation, and low-power consumption, while delivering outstanding computational performance and exceptional system response to interrupts.

Its features include the following:

- ARMv7-M architecture optimized for small-footprint embedded applications
- Arm Thumb®-2 mixed 16- and 32-bit instruction set delivers the high performance expected of a 32-bit Arm core in a compact memory size
- Fast code execution permits increased sleep mode time
- Deterministic, high-performance interrupt handling for time-critical applications
- Single-cycle multiply instruction and hardware divide
- Hardware division and fast digital-signal-processing oriented multiply accumulate
- Saturating arithmetic for signal processing
- IEEE 754-compliant single-precision Floating Point Unit (FPU)
- Memory Protection Unit (MPU) for safety-critical applications
- Full debug with data matching for watchpoint generation
  - Data Watchpoint and Trace Unit (DWT)
  - JTAG Debug Access Port (DAP)
  - Flash Patch and Breakpoint Unit (FPB)
- Trace support reduces the number of pins required for debugging and tracing
  - Instrumentation Trace Macrocell Unit (ITM)
  - Trace Port Interface Unit (TPIU) with asynchronous serial wire output (SWO)
- Optimized for single-cycle flash memory access
- Tightly connected to 8kB 4-way random replacement cache for minimal active power consumption and wait states
- Ultra-low-power consumption with integrated sleep modes
- 48MHz operation
- 1.25 DMIPS per MHz

## 8.3 Radio (RF Core)

The RF Core is a highly flexible and future proof radio module which contains an Arm Cortex-M0 processor that interfaces the analog RF and base-band circuitry, handles data to and from the system CPU side, and assembles the information bits in a given packet structure. The RF core offers a high level, command-based API to the main CPU that configurations and data are passed through. The Arm Cortex-M0 processor is not programmable by customers and is interfaced through the TI-provided RF driver that is included with the SimpleLink Software Development Kit (SDK).

The RF core can autonomously handle the time-critical aspects of the radio protocols, thus offloading the main CPU, which reduces power and leaves more resources for the user application. Several signals are also available to control external circuitry such as RF switches or range extenders autonomously.

Multiprotocol solutions are enabled through time-sliced access of the radio, handled transparently for the application through the TI-provided RF driver and dual-mode manager.

A Packet Traffic Arbitrator (PTA) scheme is available for the managed coexistence of BLE and a co-located 2.4GHz radio. This is based on 802.15.2 recommendations and common industry standards. The 3-wire coexistence interface has multiple modes of operation, encompassing different use cases and number of lines used for signaling. The radio acting as a slave is able to request access to the 2.4GHz ISM band, and the master to grant it. Information about the request priority and TX or RX operation can also be conveyed.

The various physical layer radio formats are partly built as a software defined radio where the radio behavior is either defined by radio ROM contents or by non-ROM radio formats delivered in form of firmware patches with the SimpleLink SDKs. This allows the radio platform to be updated for support of future versions of standards even with over-the-air (OTA) updates while still using the same silicon.

### 8.3.1 Bluetooth 5.2 Low Energy

The RF Core offers full support for Bluetooth 5.2 Low Energy, including the high-speed 2Mbps physical layer and the 500kbps and 125kbps long range PHYs (Coded PHY) through the TI provided Bluetooth 5.2 stack or through a high-level Bluetooth API. The Bluetooth 5.2 PHY and part of the controller are in radio and system ROM, providing significant savings in memory usage and more space available for applications.

The new high-speed mode allows data transfers up to 2Mbps, twice the speed of Bluetooth 4.2 and five times the speed of Bluetooth 4.0, without increasing power consumption. In addition to faster speeds, this mode offers significant improvements for energy efficiency and wireless coexistence with reduced radio communication time.

Bluetooth 5.2 also enables unparalleled flexibility for adjustment of speed and range based on application needs, which capitalizes on the high-speed or long-range modes respectively. Data transfers are now possible at 2Mbps, enabling development of applications using voice, audio, imaging, and data logging that were not previously an option using Bluetooth low energy. With high-speed mode, existing applications deliver faster responses, richer engagement, and longer battery life. Bluetooth 5.2 enables fast, reliable firmware updates.

### 8.3.2 802.15.4 (Thread, Zigbee, 6LoWPAN)

Through a dedicated IEEE radio API, the RF Core supports the 2.4GHz IEEE 802.15.4-2011 physical layer (2 Mchips per second Offset-QPSK with DSSS 1:8), used in Thread, Zigbee, and 6LoWPAN protocols. The 802.15.4 PHY and MAC are in radio and system ROM. TI also provides royalty-free protocol stacks for Thread and Zigbee as part of the SimpleLink SDK, enabling a robust end-to-end solution.

## 8.4 Memory

Up to 352kB nonvolatile (Flash) memory provides storage for code and data. The flash memory is in-system programmable and erasable. The last flash memory sector must contain a Customer Configuration section (CCFG) that is used by boot ROM and TI provided drivers to configure the device. This configuration is done through the ccfg.c source file that is included in all TI provided examples.

The ultra-low leakage system static RAM (SRAM) is split into up to five 16kB blocks and can be used for both storage of data and execution of code. Retention of SRAM contents in Standby power mode is enabled by

default and included in Standby mode power consumption numbers. Parity checking for detection of bit errors in memory is built-in, which reduces chip-level soft errors and thereby increases reliability. System SRAM is always initialized to zeroes upon code execution from boot.

To improve code execution speed and lower power when executing code from nonvolatile memory, a 4-way nonassociative 8kB cache is enabled by default to cache and prefetch instructions read by the system CPU. The cache can be used as a general-purpose RAM by enabling this feature in the Customer Configuration Area (CCFG).

There is a 4kB ultra-low leakage SRAM available for use with the Sensor Controller Engine which is typically used for storing Sensor Controller programs, data and configuration parameters. This RAM is also accessible by the system CPU. The Sensor Controller RAM is not cleared to zeroes between system resets.

The ROM includes a TI-RTOS kernel and low-level drivers, as well as significant parts of selected radio stacks, which frees up flash memory for the application. The ROM also contains a serial (SPI and UART) bootloader that can be used for initial programming of the device.

## 8.5 Sensor Controller

The Sensor Controller contains circuitry that can be selectively enabled in both Standby and Active power modes. The peripherals in this domain can be controlled by the Sensor Controller Engine, which is a proprietary power-optimized CPU. This CPU can read and monitor sensors or perform other tasks autonomously; thereby significantly reducing power consumption and offloading the system CPU.

The Sensor Controller Engine is user programmable with a simple programming language that has syntax similar to C. This programmability allows for sensor polling and other tasks to be specified as sequential algorithms rather than static configuration of complex peripheral modules, timers, DMA, register programmable state machines, or event routing.

The main advantages are:

- Flexibility—Data can be read and processed in unlimited manners while still [ensuring ultra-low power](#) .
- 2MHz low-power mode enables lowest possible handling of digital sensors.
- Dynamic reuse of hardware resources
- 40-bit accumulator supporting multiplication, addition and shift
- Observability and debugging options

[Sensor Controller Studio](#) is used to write, test, and debug code for the Sensor Controller. The tool produces C driver source code, which the System CPU application uses to control and exchange data with the Sensor Controller. Typical use cases may be (but are not limited to) the following:

- Read analog sensors using integrated ADC or comparators
- Interface digital sensors using GPIOs, SPI, UART, or I<sup>2</sup>C (UART and I<sup>2</sup>C are bit-banged)
- Capacitive sensing
- Waveform generation
- Very low-power pulse counting (flow metering)
- Key scan

The peripherals in the Sensor Controller include the following:

- The low-power clocked comparator can be used to wake the system CPU from any state in which the comparator is active. A configurable internal reference DAC can be used in conjunction with the comparator. The output of the comparator can also be used to trigger an interrupt or the ADC.
- Capacitive sensing functionality is implemented through the use of a constant current source, a time-to-digital converter, and a comparator. The continuous time comparator in this block can also be used as a higher-accuracy alternative to the low-power clocked comparator. The Sensor Controller takes care of baseline tracking, hysteresis, filtering, and other related functions when these modules are used for capacitive sensing.

- The ADC is a 12-bit, 200 ksamples/s ADC with eight inputs and a built-in voltage reference. The ADC can be triggered by many different sources including timers, I/O pins, software, and comparators.
- The analog modules can connect to up to eight different GPIOs.
- Dedicated SPI master with up to 6MHz clock speed

The peripherals in the Sensor Controller can also be controlled from the main application processor.

## 8.6 Cryptography

The CC2652P device comes with a wide set of modern cryptography-related hardware accelerators, drastically reducing code footprint and execution time for cryptographic operations. It also has the benefit of being lower power and improves availability and responsiveness of the system because the cryptography operations runs in a background hardware thread.

Together with a large selection of open-source cryptography libraries provided with the Software Development Kit (SDK), this allows for secure and future proof IoT applications to be easily built on top of the platform. The hardware accelerator modules are:

- **True Random Number Generator (TRNG)** module provides a true, nondeterministic noise source for the purpose of generating keys, initialization vectors (IVs), and other random number requirements. The TRNG is built on 24 ring oscillators that create unpredictable output to feed a complex nonlinear-combinatorial circuit.
- **Secure Hash Algorithm 2 (SHA-2)** with support for SHA224, SHA256, SHA384, and SHA512
- **Advanced Encryption Standard (AES)** with 128 and 256 bit key lengths
- **Public Key Accelerator** - Hardware accelerator supporting mathematical operations needed for elliptic curves up to 512 bits and RSA key pair generation up to 1024 bits.

Through use of these modules and the TI provided cryptography drivers, the following capabilities are available for an application or stack:

- **Key Agreement Schemes**
  - Elliptic curve Diffie – Hellman with static or ephemeral keys (ECDH and ECDHE)
  - Elliptic curve Password Authenticated Key Exchange by Juggling (ECJ-PAKE)
- **Signature Generation**
  - Elliptic curve Diffie-Hellman Digital Signature Algorithm (ECDSA)
- **Curve Support**
  - Short Weierstrass form (full hardware support), such as:
    - NIST-P224, NIST-P256, NIST-P384, NIST-P521
    - Brainpool-256R1, Brainpool-384R1, Brainpool-512R1
    - secp256r1
  - Montgomery form (hardware support for multiplication), such as:
    - Curve25519
- **SHA2 based MACs**
  - HMAC with SHA224, SHA256, SHA384, or SHA512
- Block cipher mode of operation
  - AESCCM
  - AESGCM
  - AESECB
  - AESCBC
  - AESCBC-MAC
- **True random number generation**

Other capabilities, such as RSA encryption and signatures as well as Edwards type of elliptic curves such as Curve1174 or Ed25519, can also be implemented using the provided hardware accelerators but are not part of the TI SimpleLink SDK for the CC2652P device.

## 8.7 Timers

A large selection of timers are available as part of the CC2652P device. These timers are:

- **Real-Time Clock (RTC)**

A 70-bit 3-channel timer running on the 32kHz low frequency system clock (SCLK\_LF). This timer is available in all power modes except Shutdown. The timer can be calibrated to compensate for frequency drift when using the LF RCOSC as the low frequency system clock. If an external LF clock with frequency different from 32.768kHz is used, the RTC tick speed can be adjusted to compensate for this. When using TI-RTOS, the RTC is used as the base timer in the operating system and should thus only be accessed through the kernel APIs such as the Clock module. The real time clock can also be read by the Sensor Controller Engine to timestamp sensor data and also has dedicated capture channels. By default, the RTC halts when a debugger halts the device.

- **General Purpose Timers (GPTIMER)**

The four flexible GPTIMERs can be used as either 4× 32 bit timers or 8× 16 bit timers, all running on up to 48MHz. Each of the 16- or 32-bit timers support a wide range of features such as one-shot or periodic counting, pulse width modulation (PWM), time counting between edges and edge counting. The inputs and outputs of the timer are connected to the device event fabric, which allows the timers to interact with signals such as GPIO inputs, other timers, DMA and ADC. The GPTIMERs are available in Active and Idle power modes.

- **Sensor Controller Timers**

The Sensor Controller contains 3 timers:

AUX Timer 0 and 1 are 16-bit timers with a  $2^N$  prescaler. Timers can either increment on a clock or on each edge of a selected tick source. Both one-shot and periodical timer modes are available.

AUX Timer 2 is a 16-bit timer that can operate at 24MHz, 2MHz or 32kHz independent of the Sensor Controller functionality. There are 4 capture or compare channels, which can be operated in one-shot or periodical modes. The timer can be used to generate events for the Sensor Controller Engine or the ADC, as well as for PWM output or waveform generation.

- **Radio Timer**

A multichannel 32-bit timer running at 4MHz is available as part of the device radio. The radio timer is typically used as the timing base in wireless network communication using the 32-bit timing word as the network time. The radio timer is synchronized with the RTC by using a dedicated radio API when the device radio is turned on or off. This ensures that for a network stack, the radio timer seems to always be running when the radio is enabled. The radio timer is in most cases used indirectly through the trigger time fields in the radio APIs and should only be used when running the accurate 48MHz high frequency crystal is the source of SCLK\_HF.

- **Watchdog timer**

The watchdog timer is used to regain control if the system operates incorrectly due to software errors. It is typically used to generate an interrupt to and reset of the device for the case where periodic monitoring of the system components and tasks fails to verify proper functionality. The watchdog timer runs on a 1.5MHz clock rate and cannot be stopped once enabled. The watchdog timer pauses to run in Standby power mode and when a debugger halts the device.

## 8.8 Serial Peripherals and I/O

The SSIs are synchronous serial interfaces that are compatible with SPI, MICROWIRE, and TI's synchronous serial interfaces. The SSIs support both SPI master and slave up to 4MHz. The SSI modules support configurable phase and polarity.

The UARTs implement universal asynchronous receiver and transmitter functions. They support flexible baud-rate generation up to a maximum of 3Mbps.

The I<sup>2</sup>S interface is used to handle digital audio and can also be used to interface pulse-density modulation microphones (PDM).

The I<sup>2</sup>C interface is also used to communicate with devices compatible with the I<sup>2</sup>C standard. The I<sup>2</sup>C interface can handle 100kHz and 400kHz operation, and can serve as both master and slave.

The I/O controller (IOC) controls the digital I/O pins and contains multiplexer circuitry to allow a set of peripherals to be assigned to I/O pins in a flexible manner. All digital I/Os are interrupt and wake-up capable, have a programmable pullup and pulldown function, and can generate an interrupt on a negative or positive edge (configurable). When configured as an output, pins can function as either push-pull or open-drain. Five GPIOs have high-drive capabilities, which are marked in **bold** in [节 6](#). All digital peripherals can be connected to any digital pin on the device.

For more information, see the [CC13x2, CC26x2 SimpleLink™ Wireless MCU Technical Reference Manual](#).

## 8.9 Battery and Temperature Monitor

A combined temperature and battery voltage monitor is available in the CC2652P device. The battery and temperature monitor allows an application to continuously monitor on-chip temperature and supply voltage and respond to changes in environmental conditions as needed. The module contains window comparators to interrupt the system CPU when temperature or supply voltage go outside defined windows. These events can also be used to wake up the device from Standby mode through the Always-On (AON) event fabric.

## 8.10 μDMA

The device includes a direct memory access (μDMA) controller. The μDMA controller provides a way to offload data-transfer tasks from the system CPU, thus allowing for more efficient use of the processor and the available bus bandwidth. The μDMA controller can perform a transfer between memory and peripherals. The μDMA controller has dedicated channels for each supported on-chip module and can be programmed to automatically perform transfers between peripherals and memory when the peripheral is ready to transfer more data.

Some features of the μDMA controller include the following (this is not an exhaustive list):

- Highly flexible and configurable channel operation of up to 32 channels
- Transfer modes: memory-to-memory, memory-to-peripheral, peripheral-to-memory, and peripheral-to-peripheral
- Data sizes of 8, 16, and 32 bits
- Ping-pong mode for continuous streaming of data

## 8.11 Debug

The debug subsystem implements two IEEE standards for debug and test purposes:

IEEE 1149.7 Class 4: Reduced-pin and Enhanced-functionality Test Access port and Boundary-scan Architecture. This is known by the acronym cJTAG (compact JTAG) and this device uses only two pins to communicate to the target: TMS (JTAG\_TMSC) and TCK (JTAG\_TCKC). This is the default mode of operation

IEEE standard 1149.1: Test Access Port and Boundary Scan Architecture Test Access Port (TAP). This standard is known by the acronym JTAG and this device uses four pins to communicate to the target: TMS (JTAG\_TMSC), TCK (JTAG\_TCKC), TDI (JTAG\_TDI) and TDO (JTAG\_TDO).

The debug subsystem also implements a user-configurable firewall to control unauthorized access to debug/test ports.

Also featured is **EnergyTrace/EnergyTrace++**. This technology implements an improved method for measuring MCU current consumption, which features a very high dynamic range (from sub- $\mu$ A to hundreds of mA), high sample rate (up to 256 kSamples/s) and the ability to track the CPU and peripheral power states.

Two modes of operation can be configured. **EnergyTrace** measures the overall MCU current consumption and allows maximum accuracy and speed to track ultra low-power states as well as the fast power transitions during radio transmission and reception. **EnergyTrace++** tracks the various power states of both the CPU and its Peripherals as well as the system clocks, allowing a close monitoring of the overall device activity.

## 8.12 Power Management

To minimize power consumption, the CC2652P supports a number of power modes and power management features (see [表 8-1](#)).

**表 8-1. Power Modes**

MODE	SOFTWARE CONFIGURABLE POWER MODES				RESET PIN HELD
	ACTIVE	IDLE	STANDBY	SHUTDOWN	
CPU	Active	Off	Off	Off	Off
Flash	On	Available	Off	Off	Off
SRAM	On	On	Retention	Off	Off
Supply System	On	On	Duty Cycled	Off	Off
Register and CPU retention	Full	Full	Partial	No	No
SRAM retention	Full	Full	Full	No	No
48MHz high-speed clock (SCLK_HF)	XOSC_HF or RCOSC_HF	XOSC_HF or RCOSC_HF	Off	Off	Off
2MHz medium-speed clock (SCLK_MF)	RCOSC_MF	RCOSC_MF	Available	Off	Off
32kHz low-speed clock (SCLK_LF)	XOSC_LF or RCOSC_LF	XOSC_LF or RCOSC_LF	XOSC_LF or RCOSC_LF	Off	Off
Peripherals	Available	Available	Off	Off	Off
Sensor Controller	Available	Available	Available	Off	Off
Wake-up on RTC	Available	Available	Available	Off	Off
Wake-up on pin edge	Available	Available	Available	Available	Off
Wake-up on reset pin	On	On	On	On	On
Brownout detector (BOD)	On	On	Duty Cycled	Off	Off
Power-on reset (POR)	On	On	On	Off	Off
Watchdog timer (WDT)	Available	Available	Paused	Off	Off

In **Active** mode, the application system CPU is actively executing code. Active mode provides normal operation of the processor and all of the peripherals that are currently enabled. The system clock can be any available clock source (see [表 8-1](#)).

In **Idle** mode, all active peripherals can be clocked, but the Application CPU core and memory are not clocked and no code is executed. Any interrupt event brings the processor back into active mode.

In **Standby** mode, only the always-on (AON) domain is active. An external wake-up event, RTC event, or Sensor Controller event is required to bring the device back to active mode. MCU peripherals with retention do not need to be reconfigured when waking up again, and the CPU continues execution from where it went into standby mode. All GPIOs are latched in standby mode.

In **Shutdown** mode, the device is entirely turned off (including the AON domain and Sensor Controller), and the I/Os are latched with the value they had before entering shutdown mode. A change of state on any I/O pin defined as a *wake from shutdown pin* wakes up the device and functions as a reset trigger. The CPU can differentiate between reset in this way and reset-by-reset pin or power-on reset by reading the reset status register. The only state retained in this mode is the latched I/O state and the flash memory contents.

The Sensor Controller is an autonomous processor that can control the peripherals in the Sensor Controller independently of the system CPU. This means that the system CPU does not have to wake up, for example to perform an ADC sampling or poll a digital sensor over SPI, thus saving both current and wake-up time that would otherwise be wasted. The [Sensor Controller Studio](#) tool enables the user to program the Sensor Controller, control its peripherals, and wake up the system CPU as needed. All Sensor Controller peripherals can also be controlled by the system CPU.

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#### 备注

The power, RF and clock management for the CC2652P device require specific configuration and handling by software for optimized performance. This configuration and handling is implemented in the TI-provided drivers that are part of the CC2652P software development kit (SDK). Therefore, TI highly recommends using this software framework for all application development on the device. The complete [SDK](#) with TI-RTOS (optional), device drivers, and examples are offered free of charge in source code.

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### 8.13 Clock Systems

The CC2652P device has several internal system clocks.

The 48MHz SCLK\_HF is used as the main system (MCU and peripherals) clock. This can be driven by the internal 48MHz RC Oscillator (RCOSC\_HF) or an external 48MHz crystal (XOSC\_HF). Radio operation requires an external 48MHz crystal.

SCLK\_MF is an internal 2MHz clock that is used by the Sensor Controller in low-power mode and also for internal power management circuitry. The SCLK\_MF clock is always driven by the internal 2MHz RC Oscillator (RCOSC\_MF).

SCLK\_LF is the 32.768kHz internal low-frequency system clock. It can be used by the Sensor Controller for ultra-low-power operation and is also used for the RTC and to synchronize the radio timer before or after Standby power mode. SCLK\_LF can be driven by the internal 32.8kHz RC Oscillator (RCOSC\_LF), a 32.768kHz watch-type crystal, or a clock input on any digital IO.

When using a crystal or the internal RC oscillator, the device can output the 32kHz SCLK\_LF signal to other devices, thereby reducing the overall system cost.

### 8.14 Network Processor

Depending on the product configuration, the CC2652P device can function as a wireless network processor (WNP - a device running the wireless protocol stack with the application running on a separate host MCU), or as a system-on-chip (SoC) with the application and protocol stack running on the system CPU inside the device.

In the first case, the external host MCU communicates with the device using SPI or UART. In the second case, the application must be written according to the application framework supplied with the wireless protocol stack.

## 9 Application, Implementation, and Layout

### 备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

For general design guidelines and hardware configuration guidelines, refer to the [CC13xx/CC26xx Hardware Configuration and PCB Design Considerations Application Report](#).

For optimum RF performance, especially when using the high-power PA, it is important to accurately follow the reference design with respect to component values and layout. Failure to do so may lead to reduced RF performance due to balun mismatch. The amplitude- and phase balance through the balun must be <1 dB and <6 degrees, respectively.

PCB stack-up is also critical for proper operation. The CC1352P EVMs and characterization boards are using a finished thickness between the top layer (RF signals) and layer 2 (ground plane) of 175  $\mu\text{m}$ . It is very important to use the same substrate thickness, or slightly thicker, in an end product implementing the CC2652P device.

### 9.1 Reference Designs

The following reference designs should be followed closely when implementing designs using the CC2652P device.

Special attention must be paid to RF component placement, decoupling capacitors, and DCDC regulator components, as well as ground connections for all of these.

All the CC1352P device reference designs are also applicable to the CC2652P device by simply disregarding the Sub-1GHz RF circuitry. For the CC2652P device, pins 3 and 4 must be left unconnected.

The high-power PA requires a specific RF matching for optimum current efficiency at 10dBm output power (2.4GHz). Refer to the application note [Optimizing the SimpleLink CC1352P for Coin Cell Operation at 10dBm Output Power](#) for details.

Integrated matched filter-balun devices can be used both at Sub-1GHz frequencies and at 2.4GHz for the low-power RF outputs. Refer to the "Integrated Passive Component" section in [CC13xx/CC26xx Hardware Configuration and PCB Design Considerations](#) for further information.

[CC1352PEM-XD7793-XD24-PA24 Design Files](#) The CC1352PEM-XD7793-XD24-PA24 reference design provides schematic, layout, and production files for the characterization board used for deriving the performance number found in this document. This board includes tuning for 2.4GHz on the high-power PA output.

For the CC2652P device, the Sub-1GHz RF circuitry can be disregarded.

[LAUNCHXL-CC1352P-2 Design Files](#) Detailed schematics and layouts for the multiband CC1352P LaunchPad evaluation board featuring 2.4GHz RF matching on the 20dBm PA output and up to 14dBm TX power at 868/915MHz.

For CC2652P, the Sub-1GHz RF circuitry can be disregarded.

[Sub-1GHz and 2.4GHz Antenna Kit for LaunchPad™ Development Kit and SensorTag](#) The antenna kit allows real-life testing to identify the optimal antenna for your application. The antenna kit includes 16 antennas for frequencies from 169MHz to 2.4GHz, including:

- PCB antennas
- Helical antennas
- Chip antennas
- Dual-band antennas for 868MHz and 915MHz combined with 2.4GHz

The antenna kit includes a JSC cable to connect to the Wireless MCU LaunchPad development kits and SensorTags.

## 10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed as follows.

### 10.1 Tools and Software

The CC2652P device is supported by a variety of software and hardware development tools.

#### Development Kit

[CC1352P-2](#)  
[LaunchPad™](#)  
[Development Kit](#)

The CC1352P-2 LaunchPad™ Development Kit enables the development of high-performance wireless applications in the 863MHz - 930MHz and 2.4GHz frequency bands that benefit from low-power operation. The kit features the CC1352P multiband and multiprotocol SimpleLink Wireless MCU with an integrated High-Power Amplifier. The kit works with the LaunchPad ecosystem, easily enabling additional functionality like sensors, displays, and more. The built-in EnergyTrace™ software is an energy-based code analysis tool that measures and displays the application's energy profile and helps to optimize it for ultra-low power consumption.

The RF configuration of the LaunchPad enables up to +14dBm output power for 863MHz - 930MHz and +20dBm output power for 2.4GHz.

[TMDSEMU110-U](#)  
[Debug Probe](#)

The TMDSEMU110-U Debug Probe enables the development of high-performance wireless applications in the entire family of SimpleLink LaunchPad™ development boards. Featuring a convenient enclosure, which grants the proper mechanical robustness for field and production environments, it supports not only multiple standards such as JTAG/cJTAG/SWD but also a UART backchannel and four GPIOs for maximum debugging flexibility. In addition, the expansion connector allows using the [TMDSEMU110-ETH](#) add-on (sold separately), which adds the full-featured XDS110 EnergyTrace™ technology with variable supply voltage from 1.8V to 3.6V and up to 800mA of supply current. The XDS110 EnergyTrace™ technology is a new method for measuring the current consumption that captures the complete operational profile of the wireless MCU.

#### Software

[SimpleLink™](#)  
[LOWPOWER F2](#)  
[SDK](#)

The SimpleLink LOWPOWER F2 Software Development Kit (SDK) provides a complete package for the development of wireless applications on the CC13XX / CC26XX family of devices. The SDK includes a comprehensive software package for the CC2652P device, including the following protocol stacks:

- Bluetooth Low Energy 4 and 5.2
- Thread (based on OpenThread)
- Zigbee 3.0
- TI 15.4-Stack—an IEEE 802.15.4-based star networking solution for Sub-1GHz and 2.4GHz
- EasyLink—a large set of building blocks for building proprietary RF software stacks
- Multiprotocol support—concurrent operation between stacks using the Dynamic Multiprotocol Manager (DMM)

The SimpleLink LOWPOWER F2 SDK is part of TI's SimpleLink MCU platform, offering a single development environment that delivers flexible hardware, software and tool options for

customers developing wired and wireless applications. For more information about the SimpleLink MCU Platform, visit <https://www.ti.com/simplelink>.

## Development Tools

<b>Code Composer Studio™ Integrated Development Environment (IDE)</b>	Code Composer Studio is an integrated development environment (IDE) that supports TI's Microcontroller and Embedded Processors portfolio. Code Composer Studio comprises a suite of tools used to develop and debug embedded applications. It includes an optimizing C/C++ compiler, source code editor, project build environment, debugger, profiler, and many other features. The intuitive IDE provides a single user interface taking you through each step of the application development flow. Familiar tools and interfaces allow users to get started faster than ever before. Code Composer Studio combines the advantages of the Eclipse® software framework with advanced embedded debug capabilities from TI resulting in a compelling feature-rich development environment for embedded developers.  CCS has support for all SimpleLink Wireless MCUs and includes support for EnergyTrace™ software (application energy usage profiling). A real-time object viewer plugin is available for TI-RTOS, part of the SimpleLink SDK.  Code Composer Studio is provided free of charge when used in conjunction with the XDS debuggers included on a LaunchPad Development Kit.
<b>Code Composer Studio™ Cloud IDE</b>	Code Composer Studio (CCS) Cloud is a web-based IDE that allows you to create, edit and build CCS and Energia™ projects. After you have successfully built your project, you can download and run on your connected LaunchPad. Basic debugging, including features like setting breakpoints and viewing variable values is now supported with CCS Cloud.
<b>IAR Embedded Workbench® for Arm®</b>	IAR Embedded Workbench® is a set of development tools for building and debugging embedded system applications using assembler, C and C++. It provides a completely integrated development environment that includes a project manager, editor, and build tools. IAR has support for all SimpleLink Wireless MCUs. It offers broad debugger support, including XDS110, IAR I-jet™, and Segger J-Link™. A real-time object viewer plugin is available for TI-RTOS, part of the SimpleLink SDK. IAR is also supported out-of-the-box on most software examples provided as part of the SimpleLink SDK.  A 30-day evaluation or a 32kB size-limited version is available through <a href="http://iar.com">iar.com</a> .
<b>SmartRF™ Studio</b>	SmartRF™ Studio is a Windows® application that can be used to evaluate and configure SimpleLink Wireless MCUs from Texas Instruments. The application will help designers of RF systems to easily evaluate the radio at an early stage in the design process. It is especially useful for the generation of configuration register values and for practical testing and debugging of the RF system. SmartRF Studio can be used either as a standalone application or together with applicable evaluation boards or debug probes for the RF device. Features of the SmartRF Studio include: <ul style="list-style-type: none"><li>Link tests—send and receive packets between nodes</li><li>Antenna and radiation tests—set the radio in continuous wave TX and RX states</li><li>Export radio configuration code for use with the TI SimpleLink SDK RF driver</li><li>Custom GPIO configuration for signaling and control of external switches</li></ul>
<b>Sensor Controller Studio</b>	Sensor Controller Studio is used to write, test and debug code for the Sensor Controller peripheral. The tool generates a Sensor Controller Interface driver, which is a set of C source files that are compiled into the System CPU application. These source files also contain the Sensor Controller binary image and allow the System CPU application to control

and exchange data with the Sensor Controller. Features of the Sensor Controller Studio include:

- Ready-to-use examples for several common use cases
- Full toolchain with built-in compiler and assembler for programming in a C-like programming language
- Provides rapid development by using the integrated sensor controller task testing and debugging functionality, including visualization of sensor data and verification of algorithms

#### CCS UniFlash

CCS UniFlash is a standalone tool used to program on-chip flash memory on TI MCUs. UniFlash has a GUI, command line, and scripting interface. CCS UniFlash is available free of charge.

#### 10.1.1 SimpleLink™ Microcontroller Platform

The SimpleLink microcontroller platform sets a new standard for developers with the broadest portfolio of wired and wireless Arm® MCUs (System-on-Chip) in a single software development environment. Delivering flexible hardware, software and tool options for your IoT applications. Invest once in the SimpleLink software development kit and use throughout your entire portfolio. Learn more on [ti.com/simplelink](http://ti.com/simplelink).

### 10.2 Documentation Support

To receive notification of documentation updates on data sheets, errata, application notes and similar, navigate to the device product folder on [ti.com/product/CC2652P](http://ti.com/product/CC2652P). In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

The current documentation that describes the MCU, related peripherals, and other technical collateral is listed as follows.

#### TI Resource Explorer

**TI Resource Explorer** Software examples, libraries, executables, and documentation are available for your device and development board.

#### Errata

##### CC2652P Silicon Errata

The silicon errata describes the known exceptions to the functional specifications for each silicon revision of the device and description on how to recognize a device revision.

#### Application Reports

All application reports for the CC2652P device are found on the device product folder at: [ti.com/product/CC2652P/technicaldocuments](http://ti.com/product/CC2652P/technicaldocuments).

#### Technical Reference Manual (TRM)

##### CC13x2, CC26x2 SimpleLink™ Wireless MCU TRM

The TRM provides a detailed description of all modules and peripherals available in the device family.

### 10.3 支持资源

**TI E2E™ 中文支持论坛**是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

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所有商标均为其各自所有者的财产。

## 10.5 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

## 10.6 术语表

### TI 术语表

本术语表列出并解释了术语、首字母缩略词和定义。

## 11 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision B (February 2021) to Revision C (April 2024)	Page
• 更改了节 1 中的关断电流值.....	1
• Changed "terminal" to "pin".....	6
• Updated Operating junction temperature range.....	9
• Updated Radio TX Current.....	11
• Updated MCU, Reset to Active Timing.....	18
• Updated MCU, Shutdown to Active Timing.....	18
• Updated DAC Offset error.....	23
• Updated DAC Max code output voltage variation.....	23
• Added LAUNCHXL-CC1352P-2 Design Files to 节 9.1 .....	47

### Changes from April 24, 2020 to February 12, 2021 (from Revision A (April 2020) to Revision B (February 2021))

Changes from April 24, 2020 to February 12, 2021 (from Revision A (April 2020) to Revision B (February 2021))	Page
• 通篇更新为蓝牙 5.2.....	1
• 向节 1, 特性的“无线电部分”列表中添加了 3 线、2 线和 1 线 PTA 共存机制.....	1
• 删除了节 1, 特性的“无线协议”列表项中的 Wi-SUN.....	1
• Changed the test condition to "Zero cycles" for the Flash sector erase time parameter in 节 7.7, <i>Nonvolatile (Flash) Memory Characteristics</i> .....	9
• Changed the test condition to 85°C for the Flash retention parameter in 节 7.7, <i>Nonvolatile (Flash) Memory Characteristics</i> .....	9
• Changed the frequency of the input tone for 14-bit and 15-bit mode in 节 7.15.1.1 .....	22
• Changed the test condition for the Accuracy parameter to 85°C in 节 7.15.3.1, <i>Temperature Sensor</i> .....	26
• Added information on SRAM parity .....	40
• Added the paragraph that begins "Integrated matched filter-balun devices can be used..." in 节 9.1, <i>Reference Designs</i> .....	47

## 12 Mechanical, Packaging, and Orderable Information

### 12.1 Packaging Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CC2652P1FRGZR	Active	Production	VQFN (RGZ)   48	2500   LARGE T&R	Yes	NIPDAU   NIPDAUAG	Level-3-260C-168 HR	-40 to 85	CC2652 P1F
CC2652P1FRGZR.A	Active	Production	VQFN (RGZ)   48	2500   LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	CC2652 P1F
CC2652P1FRGZR.B	Active	Production	VQFN (RGZ)   48	2500   LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	CC2652 P1F

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

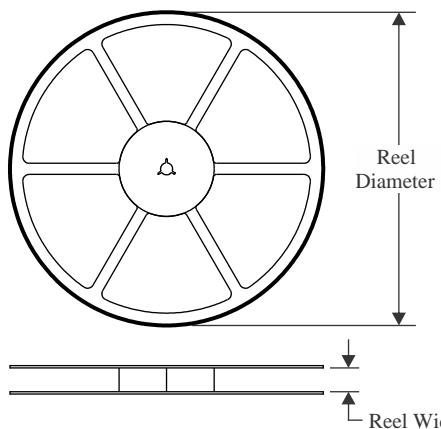
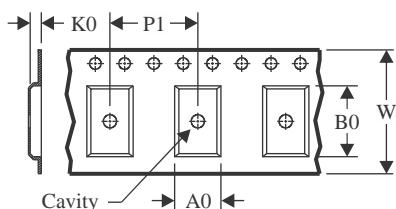
<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

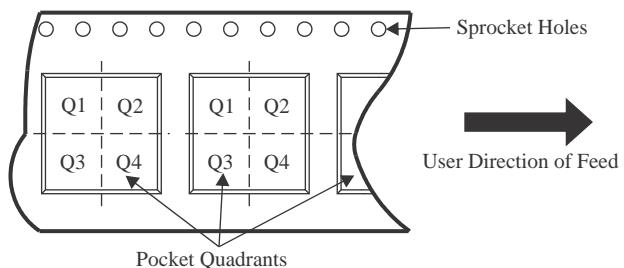
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

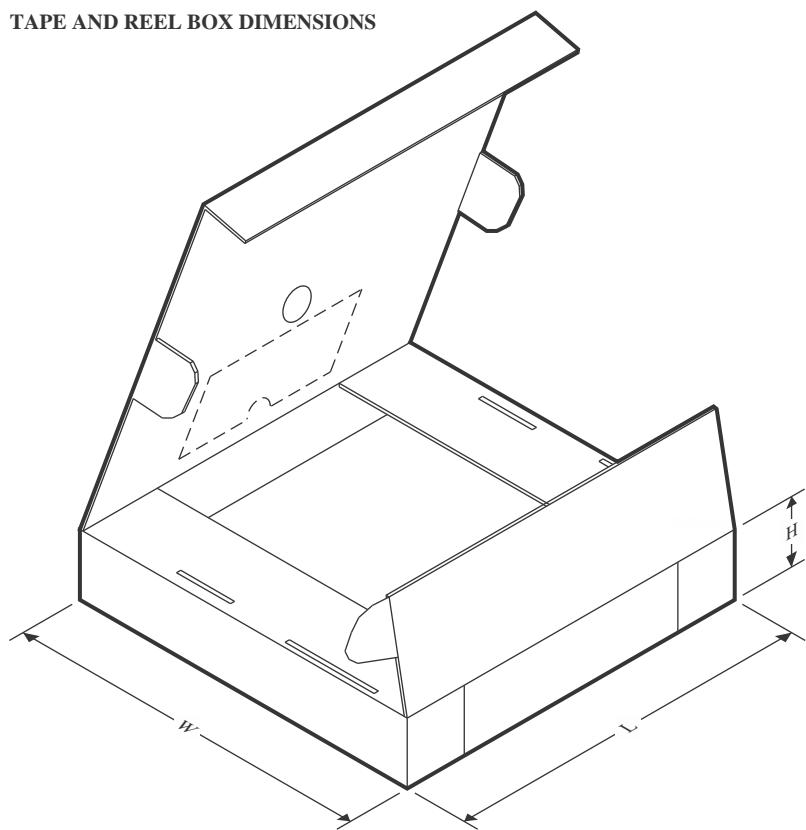
**TAPE AND REEL INFORMATION**
**REEL DIMENSIONS**

**TAPE DIMENSIONS**


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CC2652P1FRGZR	VQFN	RGZ	48	2500	330.0	16.4	7.3	7.3	1.1	12.0	16.0	Q2

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CC2652P1FRGZR	VQFN	RGZ	48	2500	367.0	367.0	35.0

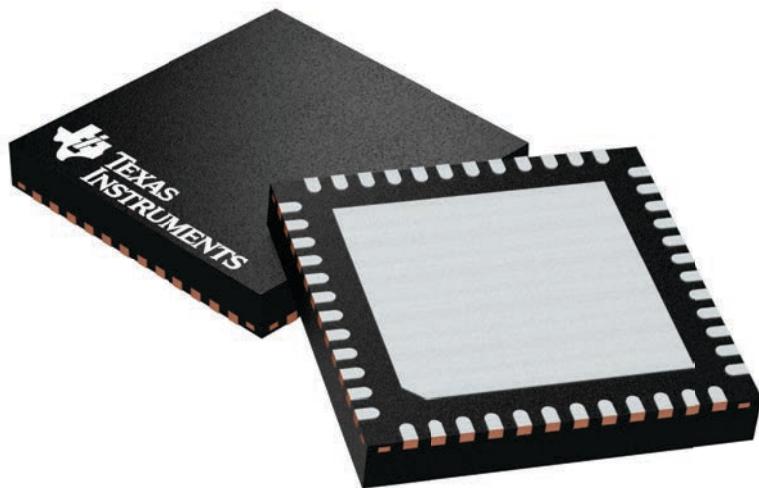
## GENERIC PACKAGE VIEW

**RGZ 48**

**VQFN - 1 mm max height**

7 x 7, 0.5 mm pitch

PLASTIC QUADFLAT PACK- NO LEAD



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

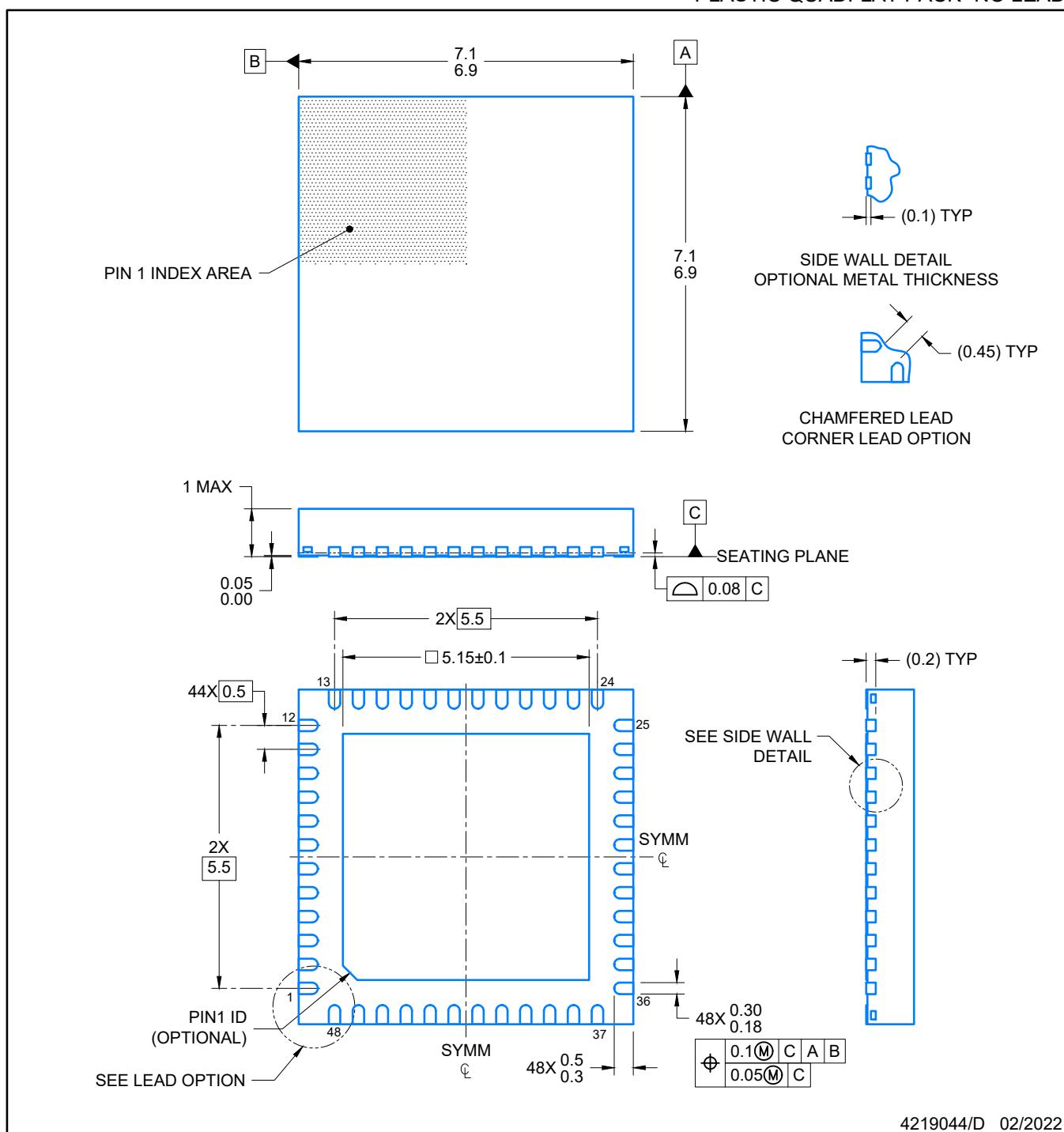
4224671/A

# PACKAGE OUTLINE

## VQFN - 1 mm max height

RGZ0048A

PLASTIC QUADFLAT PACK- NO LEAD



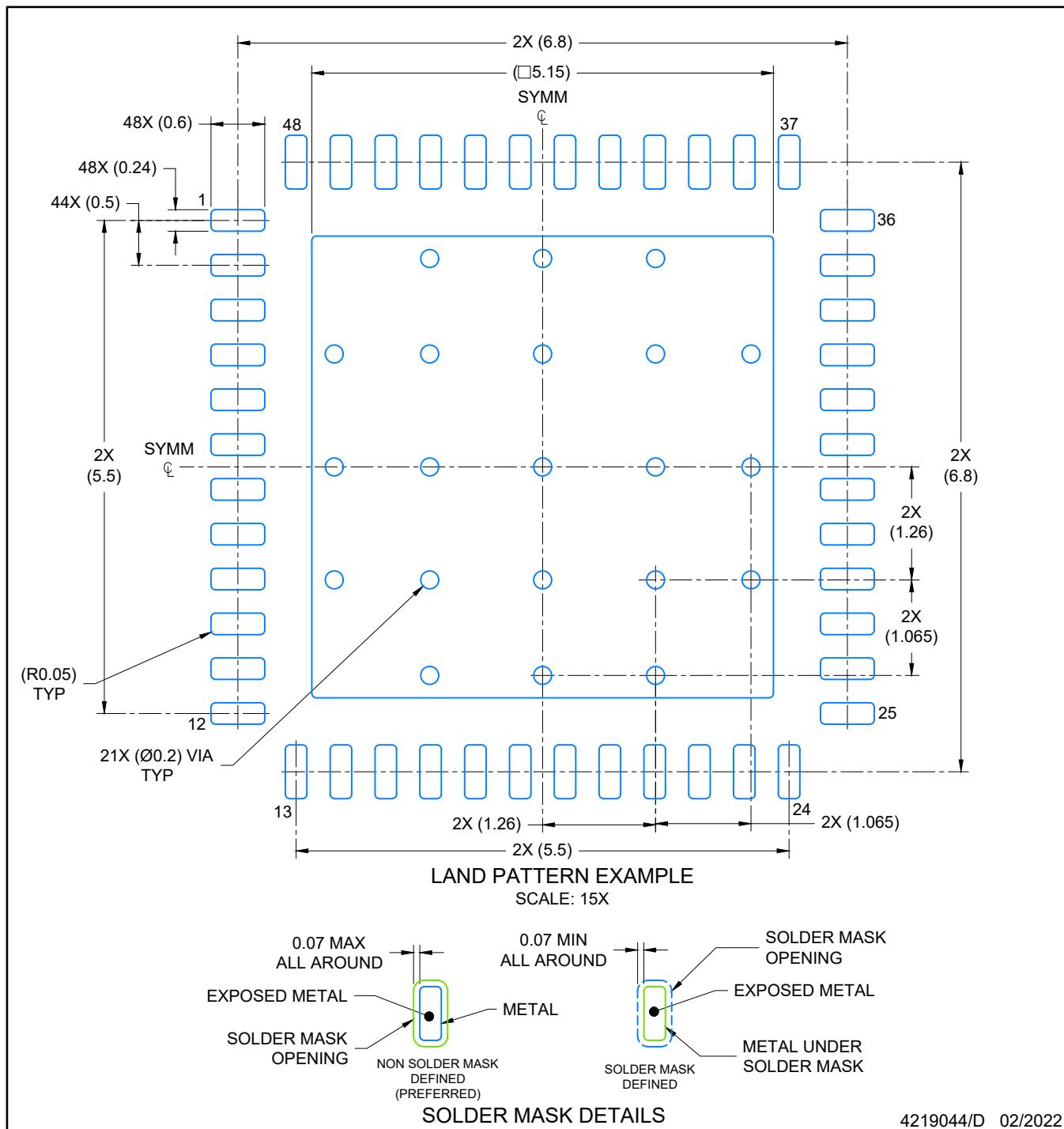
### NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

## EXAMPLE BOARD LAYOUT

## **VQFN - 1 mm max height**

## PLASTIC QUADFLAT PACK- NO LEAD



NOTES: (continued)

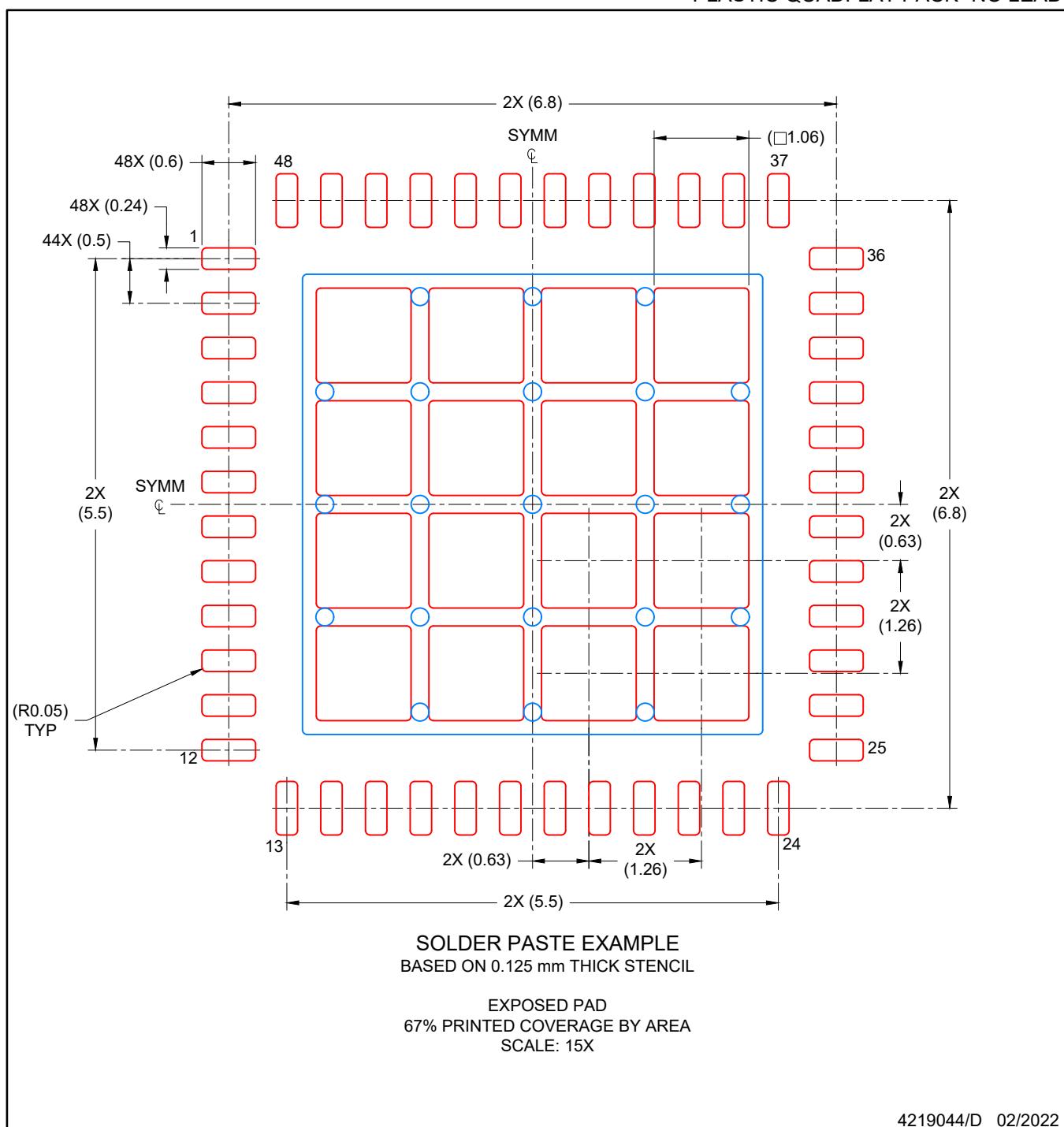
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

# EXAMPLE STENCIL DESIGN

VQFN - 1 mm max height

RGZ0048A

PLASTIC QUADFLAT PACK- NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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